

LP8725 Power Management Unit for Application or Multimedia Processors and Subsystems

Check for Samples: [LP8725](#)

FEATURES

- Two High-Efficiency Step-Down DC-DC Converters, $I_{OUT} = 600$ mA, With a 4-MHz Switching Frequency Using Small 1- μ H Inductors, With Options up to 800 mA
- Three Digital LDOs for up to 300-mA Load Current Each
- Two Low-Noise Analog 300-mA LDOs
- Two Low-Input Low-Output Regulators, $I_{OUT} = 300$ mA
- I²C-Compatible Interface for Control of Internal Registers
- Adjustable Startup Sequence Through Serial Interface or Configuration
- Thermal Shutdown Protection

APPLICATIONS

- Multimedia Processors
- Portable Handheld Products

KEY SPECIFICATIONS

- 190 mV typ. Dropout Voltage on digital LDOs @ 300 mA
- 2% typ. Output Voltage Accuracy on digital and analog LDOs
- 10 μ Vrms Output Noise on analog LDOs
- $\pm 2\%$ typ. Output Voltage Bucks up to 93% efficiency
- 30-bump DSBGA package (0.5 mm pitch)

DESCRIPTION

This device is a multi-function programmable Power Management Unit (PMU), optimized for sub block power solutions. This device integrates two highly efficient 600-mA step-down DC-DC converters configurable up to 800-mA load with Dynamic Voltage Scaling (DVS) via the serial interface, two low-noise analog LDOs, three digital LDOs for up to 300 mA load current each, two Low-Input Low-Output (LILO) regulators, and an I²C-compatible serial interface to allow a host controller access to the internal control registers. The device also features programmable power-on sequencing. LDO regulators provide high PSRR and low noise ideally suited for supplying power to both analog and digital loads.

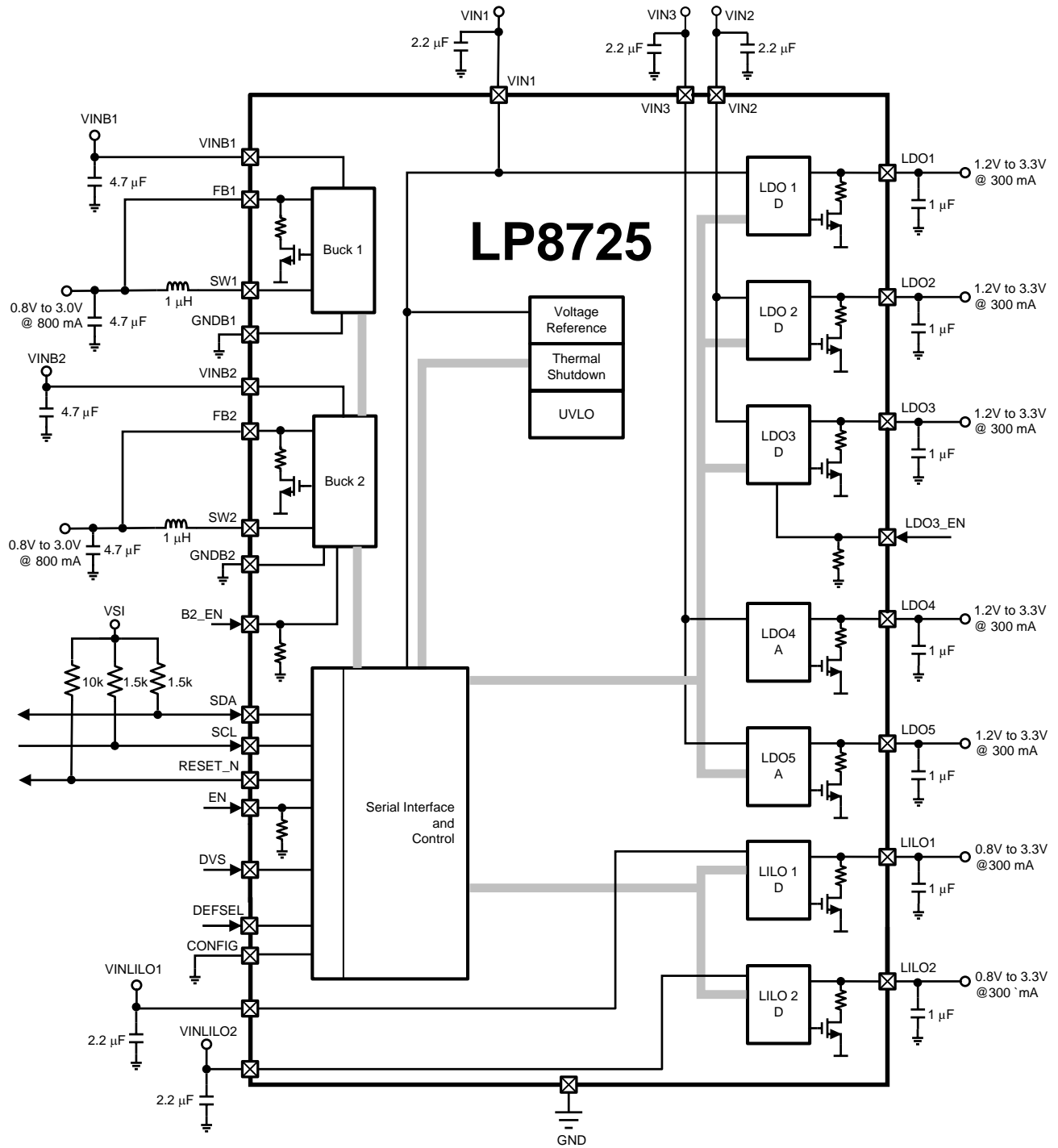
The device can be configured either as a Sub_PMU for modules (for example, camera or multimedia modules) or as a stand-alone PMU that powers the processor itself.



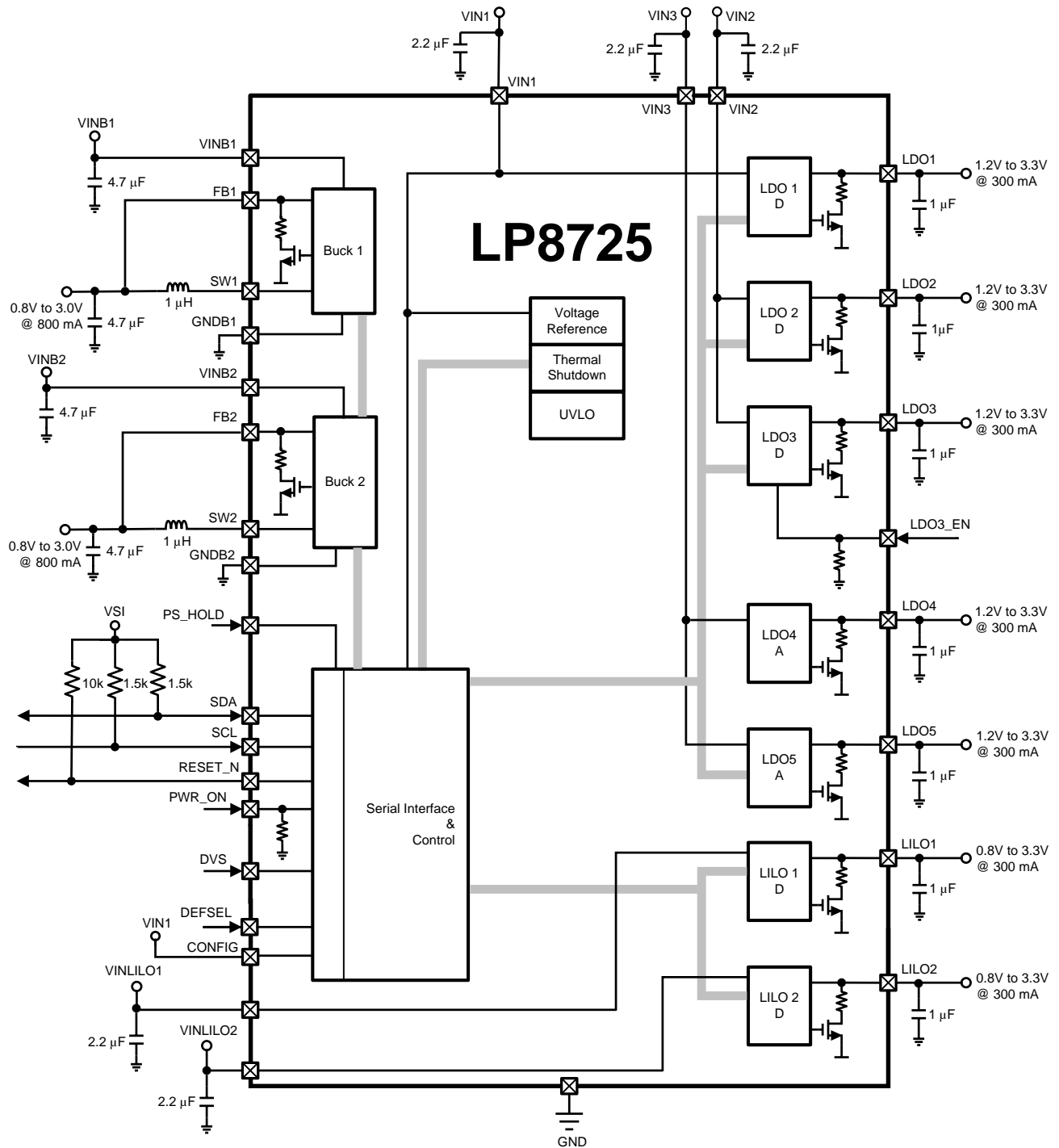
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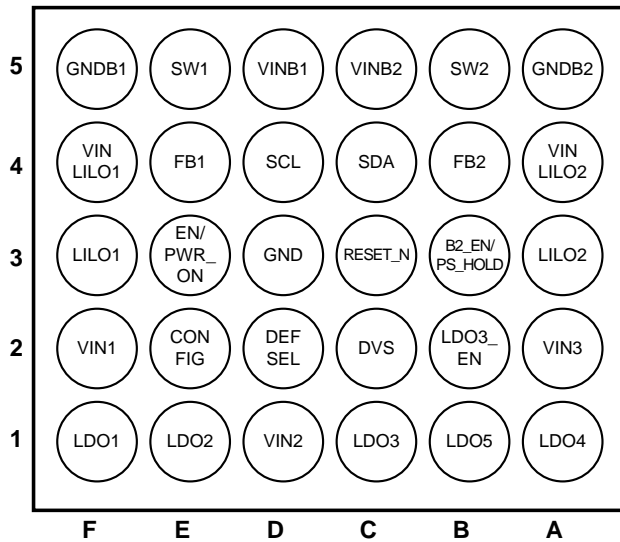
TYPICAL APPLICATION (SUB-PMU)



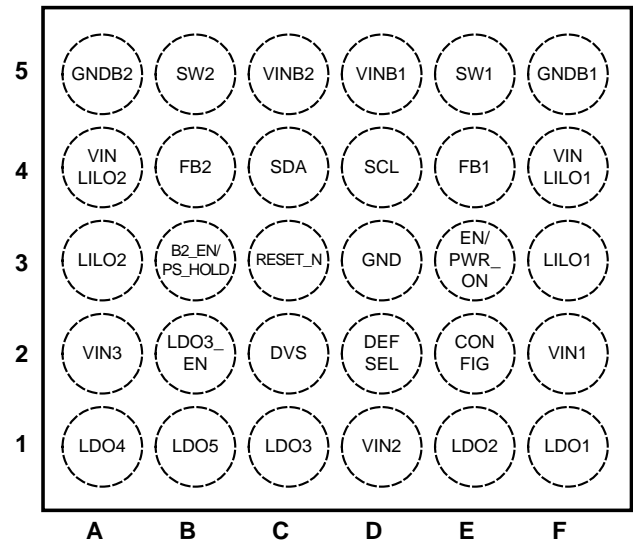
TYPICAL APPLICATION (PMU)



CONNECTION DIAGRAMS



Bottom View



Top View

PIN DESCRIPTIONS

Name	Pin No.	Description
B2_EN/PS_HOLD	B3	CONFIG=0: B2_EN is the enable for BUCK2 output if this pin is high and if BUCK2_EN register bit is set to 0. (B2_EN and the register bit are logical OR.) Internal 500 kΩ pull-down resistor in this configuration only. CONFIG=1: PS_HOLD is a power supply hold input from an external processor.
CONFIG	E2	Connect to GND for SUB_PMU or connect to VIN1 for PMU.
DEFSEL	D2	Control input that sets default voltages and start-up sequence. Must be hard wired to VIN1 or GND for specific application. When DEFSEL=VIN1 then setup 1 is used for default voltages and startup sequences. When DEFSEL=GND then setup 2 is used for default voltages and startup sequences.
DVS	C2	Dynamic Voltage Scaling (operational when REG 0x00<2> is '0'). DVS=1 then BUCK voltage set BUCK1_V1 is in use. DVS=0 then BUCK voltage set BUCK1_V2 is in use. This pin must be driven to its logic high or low whenever the BUCK1 or BUCK2 outputs are enabled.
EN/PWR_ON	E3	CONFIG=0: EN=1 turns on outputs or standby mode if EN=0. CONFIG=1: PWR_ON=1 starts power up sequence after 30 ms of de-bounce time. Internal 500K pull-down resistor.
FB1	E4	BUCK1 Feedback. Active pull-down when BUCK1 turns off.
FB2	B4	BUCK2 Feedback. Active pull-down when BUCK2 turns off.
GND	D3	IC Ground
GNDB1	F5	BUCK1 Ground.
GNDB2	A5	BUCK2 Ground.
LDO1	F1	LDO1 output.
LDO2	E1	LDO2 output.
LDO3	C1	LDO3 output.
LDO3_EN	B2	Enable for LDO3 output if this pin is high and if LDO3_EN register bit is set to 0. (LDO3_EN and the register bit are logical OR.) Internal 500 kΩ pull-down resistor.
LDO4	A1	LDO4 output.
LDO5	B1	LDO5 output
LIL01	F3	LIL01 output.
LIL02	A3	LIL02 output.
RESET_N	C3	CONFIG=0: Goes high typ. 30 ms after EN=1 and goes low when EN=0. CONFIG=1: Goes high typ. 60 ms after PWR_ON=1 and goes low 30 ms after PS_HOLD=0. External pull-up resistor is needed, typical 10 kΩ.
SCL	D4	Serial Interface Clock Input. External pull-up resistor is needed, typical 1.5 kΩ.
SDA	C4	Serial Interface Data Input/Output. Open Drain output, external pull-up resistor is needed, typical 1.5 kΩ.
SW1	E5	BUCK1 Switch node of DC-DC converter BUCK1.
SW2	B5	BUCK2 Switch node of DC-DC converter BUCK2.
VIN1	F2	Input for LDO1.
VINB1	D5	Input for BUCK1.
VIN2	D1	Input for LDO2 and LDO3.
VINB2	C5	Input for BUCK2.
VIN3	A2	Input for LDO4 and LDO5.
VINLIL01	F4	Input for LIL01.
VINLIL02	A4	Input for LIL02.



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

DEVICE DESCRIPTION

Operation Modes

POWER-ON-RESET: In SUB_PMU configuration - After VIN1 goes above UVLO high threshold, then all internal registers of LP8725 are reset to the default values from the DEFSEL setting, after which LP8725 goes to STANDBY mode. In PMU configuration - When PWR_ON goes high while VIN1 is above the UVLO high threshold, all internal registers of LP8725 are reset to the default values from the DEFSEL setting. This process duration max is typically 500 μ s.

STANDBY: In STANDBY mode only serial interface is working and all other PMU functions are disabled – PMU is in low-power condition. In STANDBY mode LP8725 can be (re)configured via Serial Interface. The LP8725 only enters STANDBY mode automatically in SUB_PMU configuration.

STARTUP: STARTUP sequence is defined by registers contents. STARTUP sequence starts:

- 1) If rising edge on EN-pin in SUB_PMU configuration.
- 2) After cooling down from thermal shutdown event if EN=1 in SUB_PMU configuration.
- 3) If PWR_ON is still high after 30 ms (typical de-bounce time) in PMU configuration. It is not recommended to write to LP8725 registers during STARTUP. If doing so then current STARTUP sequence may become undefined.

In SUB_PMU configuration RESET_N is de-asserted 30 ms (typical) after EN=1. In PMU configuration RESET_N is de-asserted a further 30 ms (typical) after PWR_ON de-bounce time has ended.

It is not recommended to write to LP8725 registers during startup. If doing so then current STARTUP sequence may become undefined.

IDLE: The LP8725 will enter into IDLE mode (normal operating mode) after end of startup sequence. In IDLE mode all LDOs and BUCK can be enabled/disabled via Serial Interface. Also in IDLE mode the LP8725 can be (re)configured via Serial Interface.

SHUTDOWN: SHUTDOWN sequence follows the reverse order of the startup sequence defined by registers contents:

- 1) If falling edge on EN-pin in SUB_PMU configuration.
- 2) If PS_HOLD and PWR_ON both go low for typically 30 ms in PMU configuration. Device immediately shuts down if the temperature exceeds thermal shutdown threshold TSD +160°C.

RESET_N is asserted when the device starts to shut down.

It is not recommended to write to LP8725 registers during SHUT DOWN. If doing so then current SHUTDOWN sequence may become undefined.

In SUB_PMU configuration the device shuts down to STANDBY mode.

In PMU configuration the device shuts down completely (so registers will be reset on next PWR_ON high).

SLEEP: The load current for each of the LDO outputs should be no greater than 5mA when the device is put into SLEEP mode. In Sleep mode Ground current is minimized. SLEEP mode is controlled by the serial interface, Register 0x00 bit 1.

SLEEP Mode is controlled by the Serial Interface.

Table 1. Application Configuration⁽¹⁾⁽²⁾

CONFIG	Application	Pin B3 Function	Pin E3 Function	Slave Address, DEFSEL = 1	Slave Address, DEFSEL = 0
GND	SUB_PMU	B2_EN	EN	7h78	7h7A
VIN1	PMU	PS_HOLD	PWR_ON	7h79	7h7B

(1) The LP8725 and LP8725-A are both configured as either SUB_PMU or PMU by the wiring of the CONFIG pin on the application of power to the device.

(2) These are dependent on whether DEFSEL is connected to VIN1 or GND when PWR_ON/EN=1.

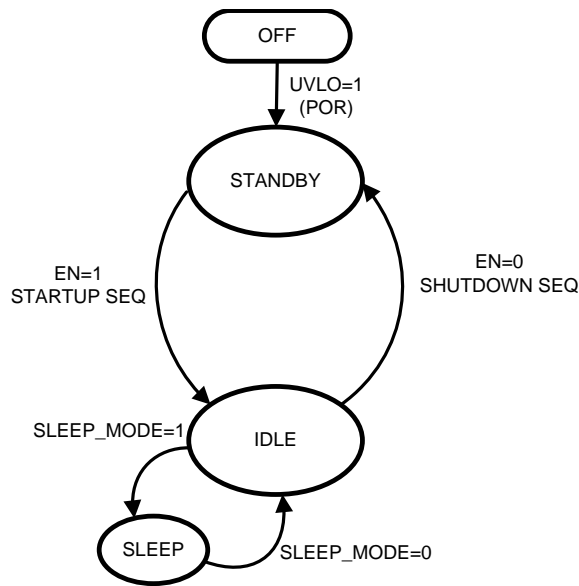


Figure 1. SUB-PMU Mode, CONFIG = 0

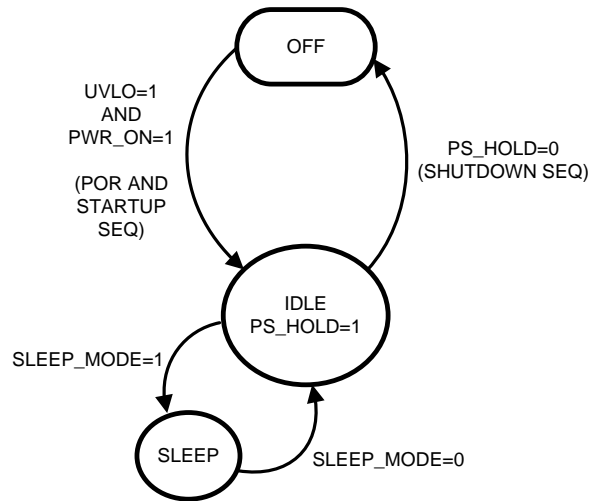


Figure 2. PMU Mode, CONFIG = 1

Additional Functions

DVS: Dynamic Voltage Scaling allows using 2 set voltages for BUCKs. This is controlled via Serial Interface. BUCK1 can also be controlled by the external DVS pin.

FAULT DETECTION If BUCK1/BUCK2 and LDO1 are not masked then if one of the outputs is pulled down - e.g., short circuit, then RESET_N is asserted (low)..

Table 2. Default Start-Up Enable Sequence⁽¹⁾

Part No.	DEFSEL	Start-Up Sequence	Shut Down Sequence
LP8725	VIN1 (setup 1)	BUCK1 then BUCK2 and LILO2 then LDO1, LDO2, LDO4 and LDO5 then LDO3 and LILO1	In reverse order of start-up sequence.
LP8725	GND (setup 2)	BUCK1 and LILO2 then BUCK2, LDO1, LDO2, LDO5 and LILO1 then LDO3 and LDO4.	In reverse order of start-up sequence.
LP8725-A	VIN1 (setup 1)	LDO1, LDO2, LDO5 and LILO1 then LDO4 and LILO2	In reverse order of start-up sequence.
LP8725-A	GND (setup 2)	BUCK1 and BUCK2 then LDO2 and LDO3 then LDO1, LDO4 and LDO5 then LILO1 and LILO2	In reverse order of start-up sequence.
LP8725-B	VIN1 or GND	BUCK1 then BUCK2 then LDO1 then LILO2	In reverse order of start-up sequence.
LP8725-C	VIN1 or GND	BUCK1 then BUCK2 and LDO5 then LDO1 and LDO2 and LILO 1 and LILO 2 then LDO3 and LDO4	In reverse order of start-up sequence.
LP8725-D	VIN1 or GND	BUCK1 then BUCK2, LDO3, LILO1 and LILO2	In reverse order of start-up sequence.

(1) These are dependent on whether DEFSEL is connected to VIN1 or GND when PWR_ON/EN=1.

Power On and Power Off Sequences

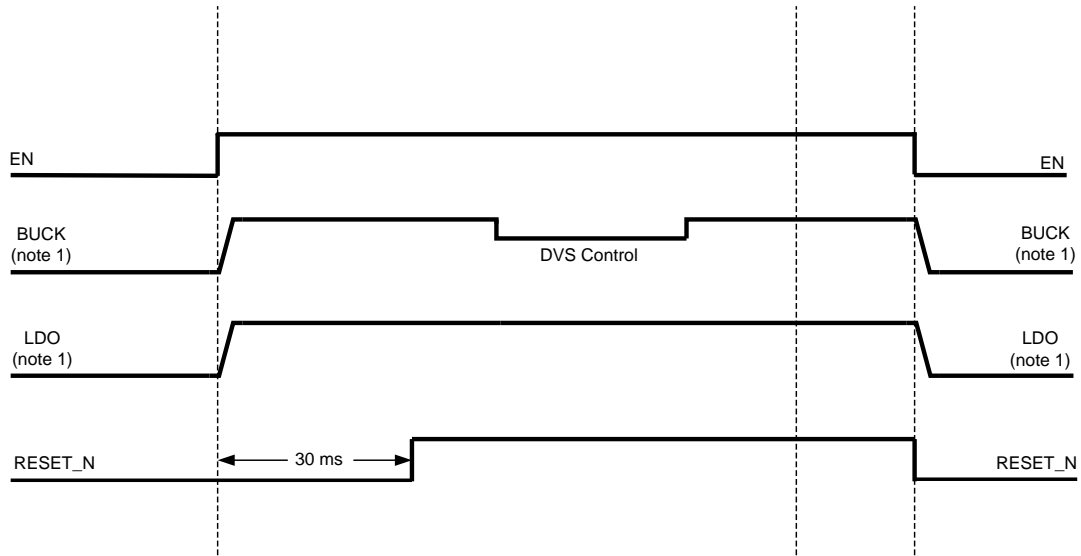
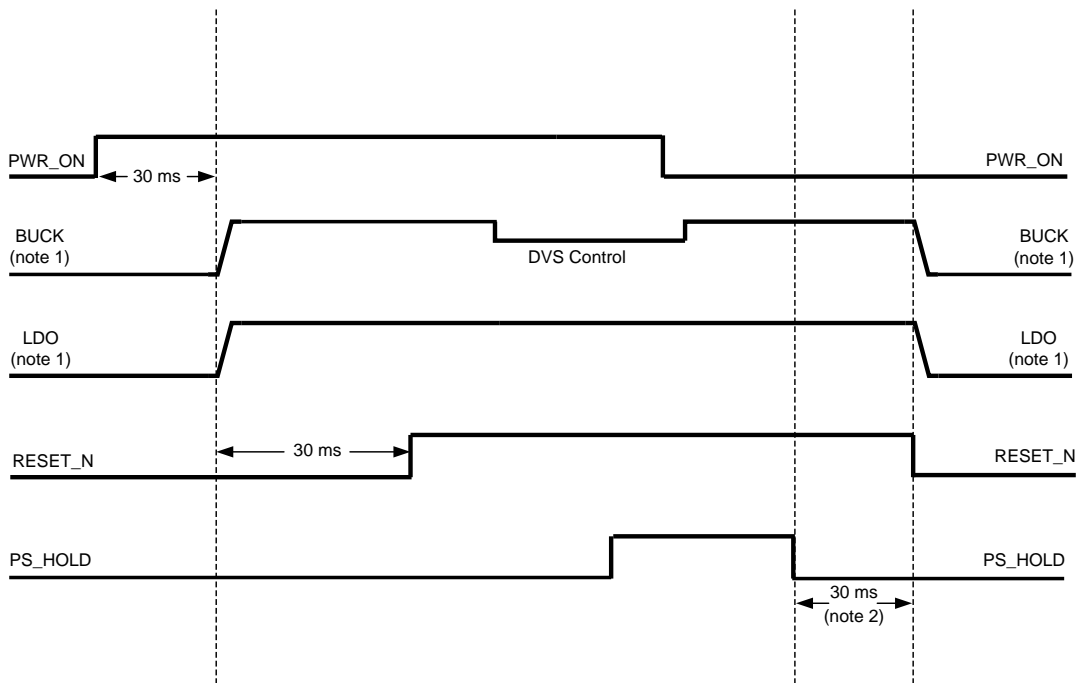


Figure 3. Simplified startup Sequence if CONFIG=GND (SUB_PMU)



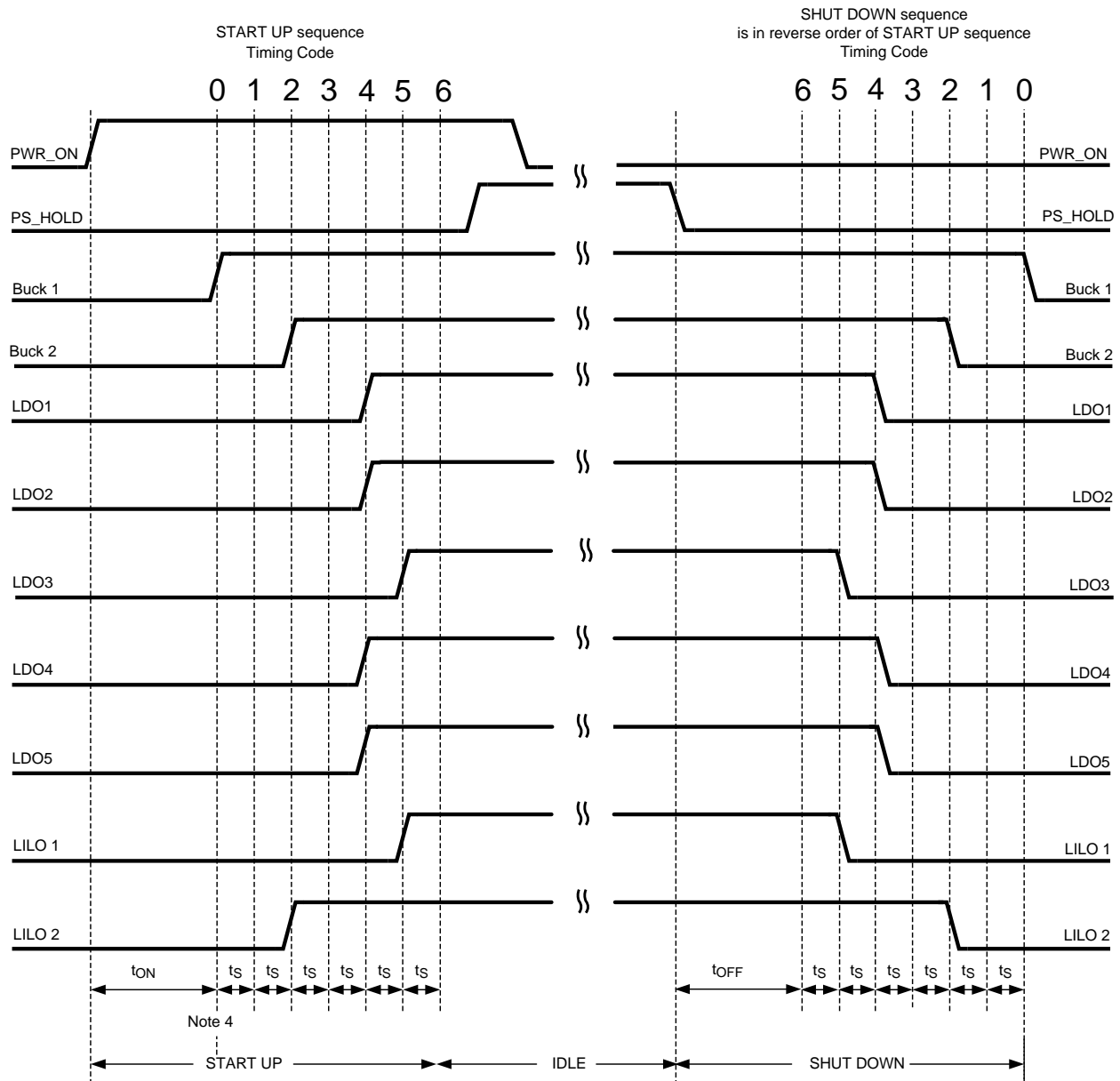
All timing is typical.

Note 1 See detailed on/off sequence diagrams for the different DEFSEL options.

Note 2 PS_HOLD needs to be held low for >30 ms before RESET_N is asserted low. PMU should then start shutdown sequence opposite of startup sequence.

Figure 4. Simplified Startup Sequence if CONFIG=VIN1 (PMU)

Figure 5. LP8725 Startup and Shutdown Sequence if CONFIG=VIN1 Note 1, Note 2



All timing is typical.

$t_{ON/OFF}$ 30 ms typ. de-bounce times

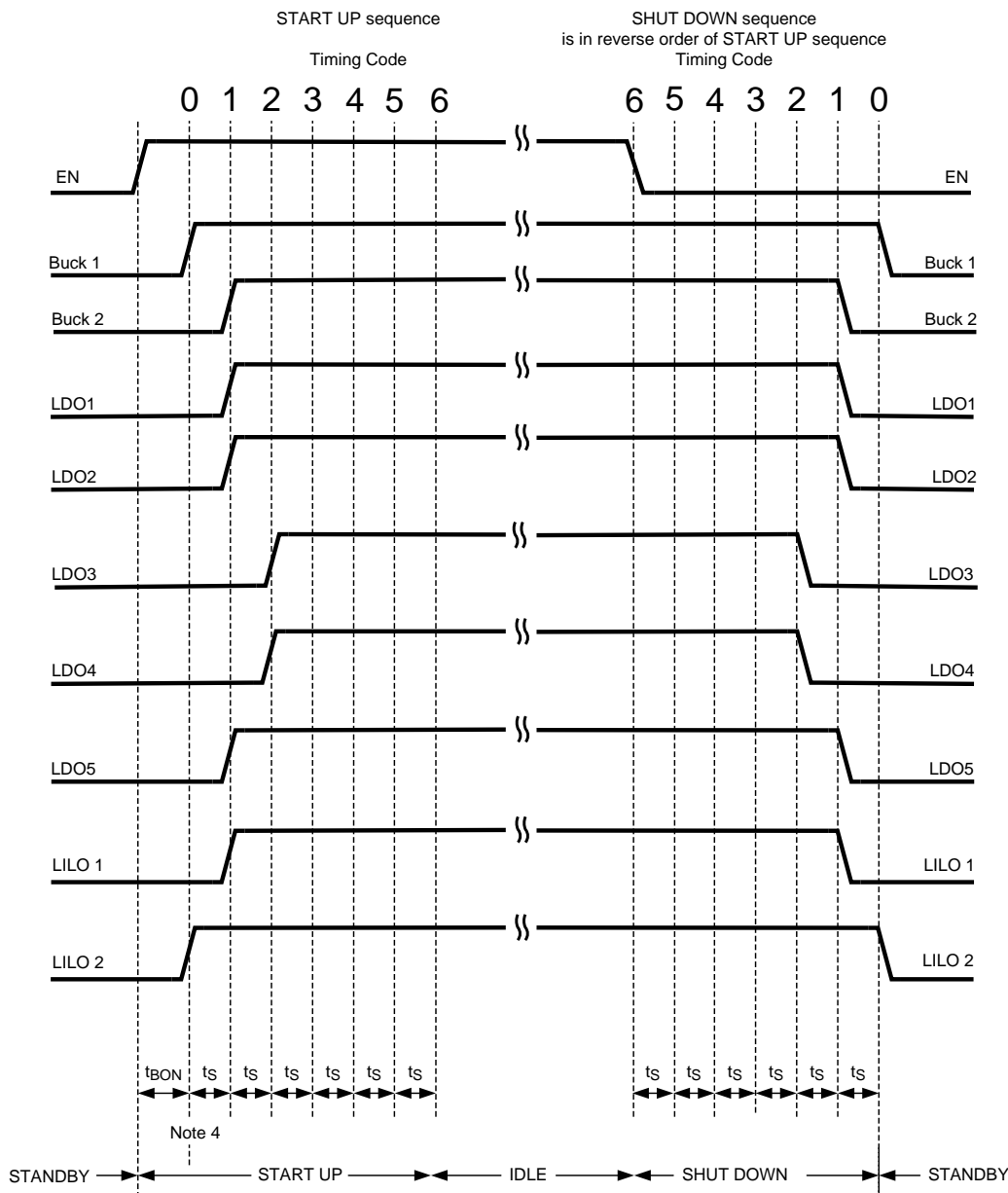
t_s Programmable time steps. (Typically 64 μ s/step.) Time step accuracy is defined by OSC frequency accuracy.

Note 1 STARTUP and SHUTDOWN sequences are defined by registers. Sequences given here are valid if there the registers are not rewritten via Serial Interface.

Note 2 The timing showed here define time points when LDOs and BUCK are enabled/disabled. Enabling /disabling process duration depends on voltages and loading conditions. Buck startup duration is typically 170 μ s. LDO startup duration is typically 35 μ s. For details please see LDOs and BUCK Electrical Specifications.

Note 4 At this time point registers are reset to POR default values.

Figure 6. LP8725 Startup and Shutdown Sequence if CONFIG=GND, DEFSEL=GND Note 1, Note 2



All timing is typical.

t_{BON} 75 μ s - Reference and bias turn ON.

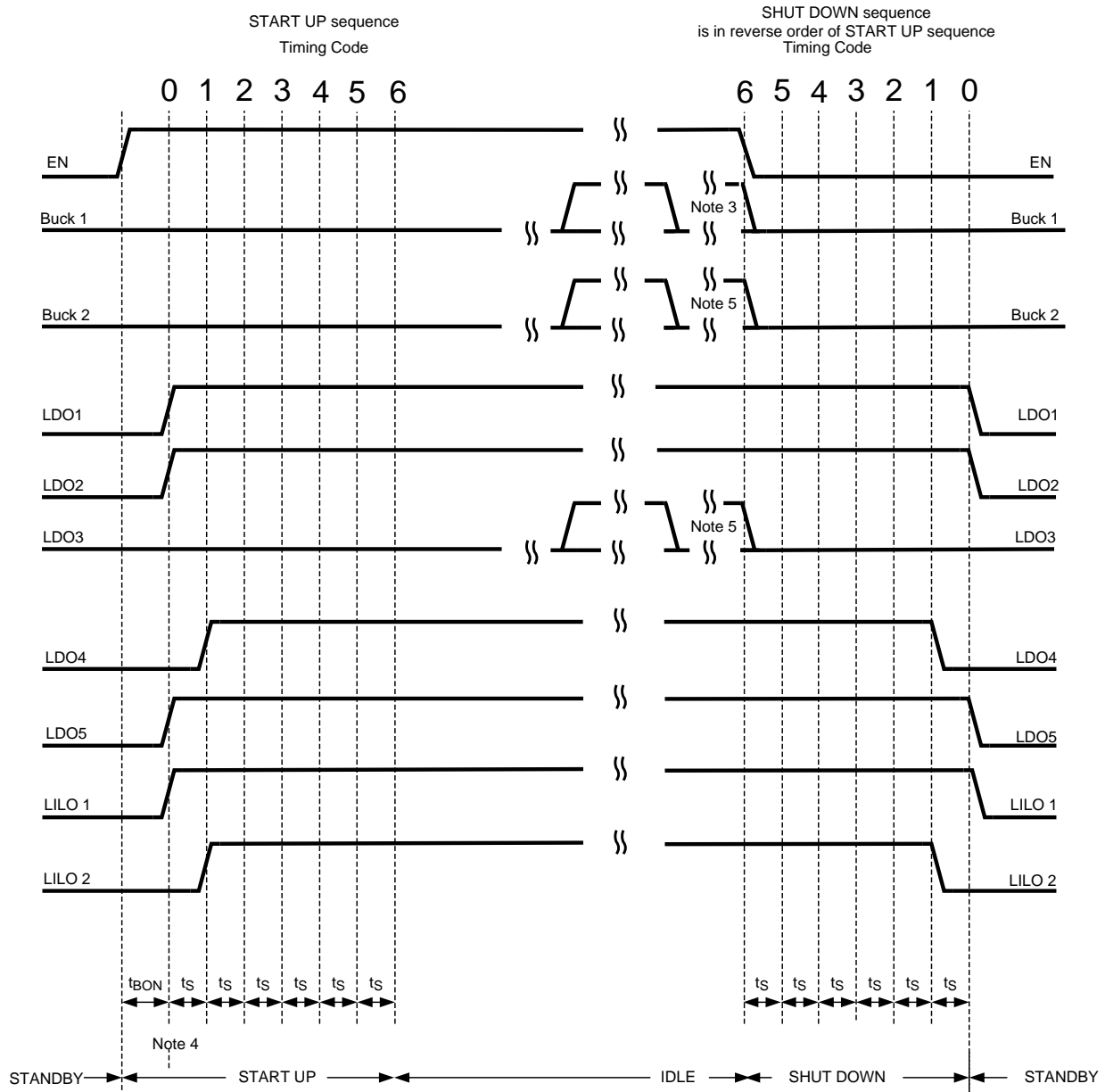
t_s Programmable time steps. (**Typically 64 μ s/step.**) Time step accuracy is defined by OSC frequency accuracy.

Note 1 STARTUP and SHUTDOWN sequences are defined by registers. Sequences given here are valid if there the registers are not rewritten via Serial Interface.

Note 2 The timing showed here define time points when LDOs and BUCK are enabled/disabled. Enabling /disabling process duration depends on voltages and loading conditions. Buck startup duration is typically 170 μ s. LDO startup duration is typically 35 μ s. For details please see LDOs and BUCK Electrical Specifications.

Note 4 At this time point registers are reset to POR default values.

Figure 7. LP8725-A Startup and Shutdown Sequence if CONFIG=GND, DEFSEL=VIN1 Note 1, Note 2



All timing is typical.

t_{BON} 75 μ s - Reference and bias turn ON.

t_s Programmable time steps. (Typically 64 μ s/step.) Time step accuracy is defined by OSC frequency accuracy.

Note 1 STARTUP and SHUTDOWN sequences are defined by registers. Sequences given here are valid if there the registers are not rewritten via Serial Interface.

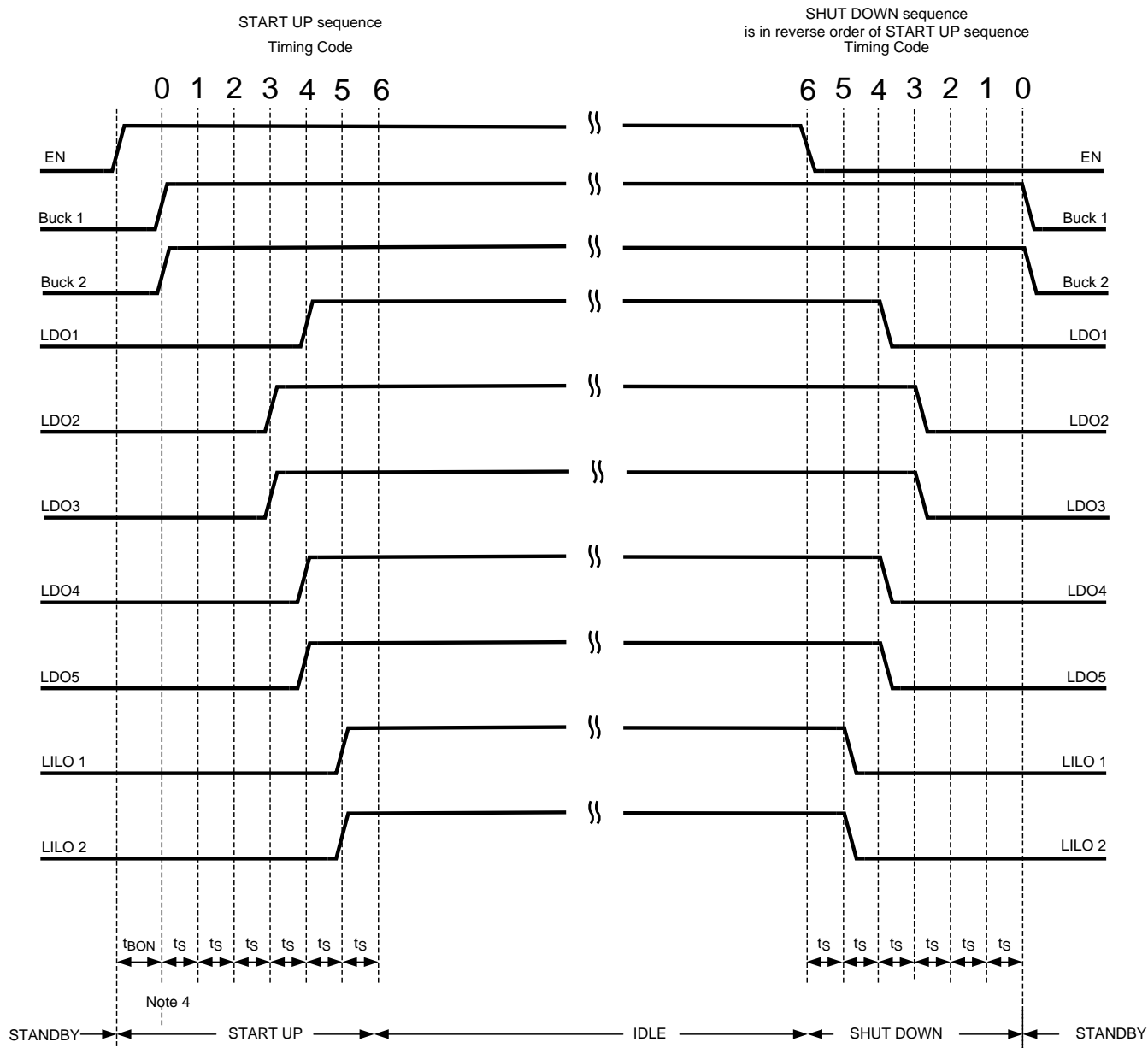
Note 2 The timing showed here define time points when LDOs and BUCK are enabled/disabled. Enabling /disabling process duration depends on voltages and loading conditions. Buck startup duration is typically 170 μ s. LDO startup duration is typically 35 μ s. For details please see LDOs and BUCK Electrical Specifications.

Note 3 BUCK1 is disabled. If it is enabled via Serial Interface and the startup sequence is not changed, then it will be disabled, with no delay, from falling edge of EN-pin.

Note 4 At this time point registers are reset to POR default values.

Note 5 BUCK2 and LDO3 are enabled by B2_EN and LDO3_EN respectively (or via serial interface). If these inputs are high when EN goes high then these outputs turn on after $t_s=6$.

Figure 8. LP8725-A Startup and Shutdown Sequence if CONFIG=GND, DEFSEL=GND Note 1, Note 2



All timing is typical.

t_{BON} 75 μ s - Reference and bias turn ON.

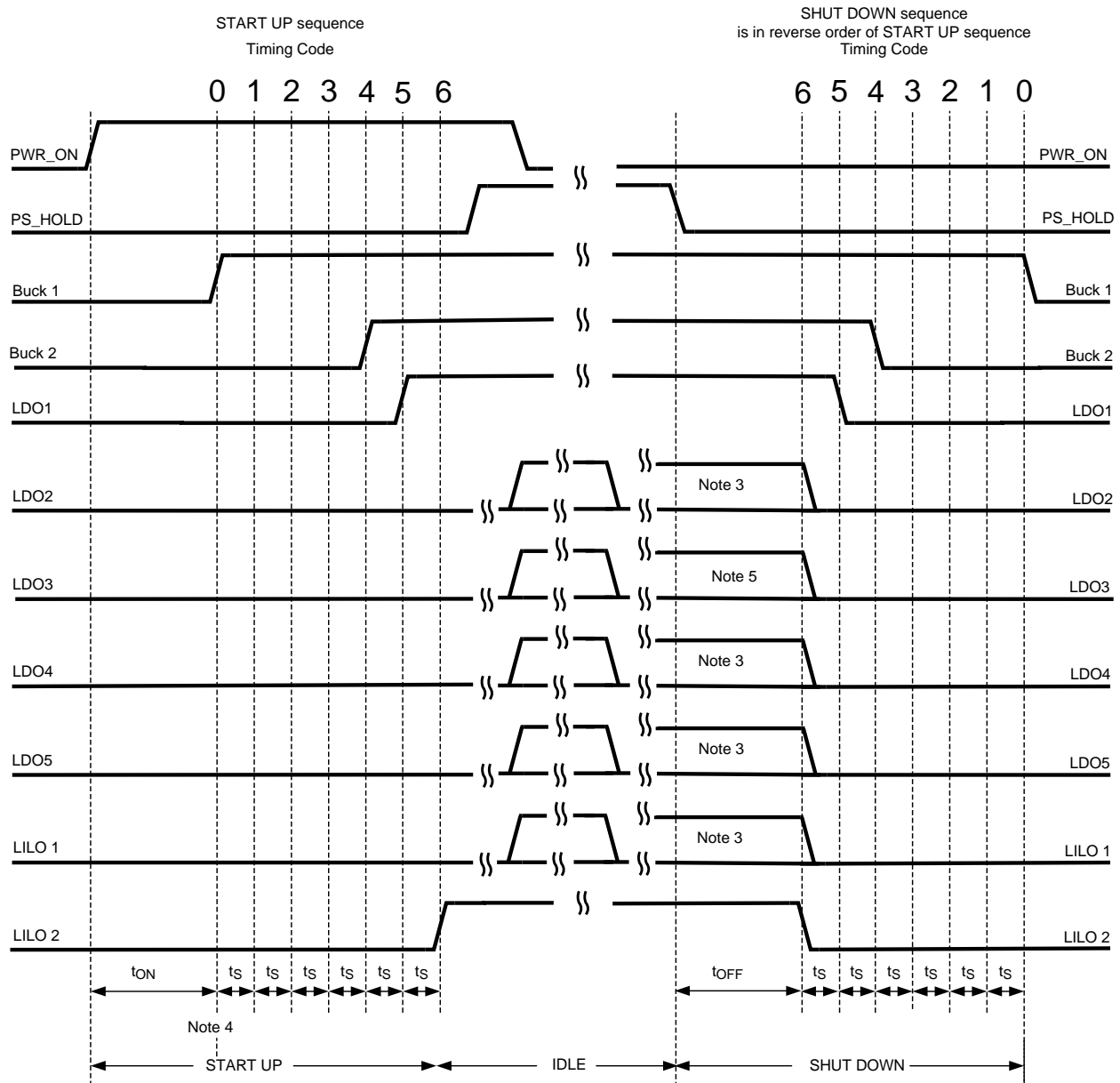
t_s Programmable time steps. (**Typically 64 μ s/step.**) Time step accuracy is defined by OSC frequency accuracy.

Note 1 STARTUP and SHUTDOWN sequences are defined by registers. Sequences given here are valid if there the registers are not rewritten via Serial Interface.

Note 2 The timing showed here define time points when LDOs and BUCK are enabled/disabled. Enabling /disabling process duration depends on voltages and loading conditions. Buck startup duration is typically 170 μ s. LDO startup duration is typically 35 μ s. For details please see LDOs and BUCK Electrical Specifications.

Note 4 At this time point registers are reset to POR default values.

Figure 9. LP8725-B Startup and Shutdown Sequence if CONFIG=VIN1, DEFSEL=VIN1 or DEFSEL=GND Note 1, Note 2



All timing is typical.

$t_{ON/OFF}$ 30 ms typ. de-bounce times.

t_s Programmable time steps. (Typically 64 μ s/step.) Time step accuracy is defined by OSC frequency accuracy.

Note 1 STARTUP and SHUTDOWN sequences are defined by registers. Sequences given here are valid if there the registers are not rewritten via Serial Interface.

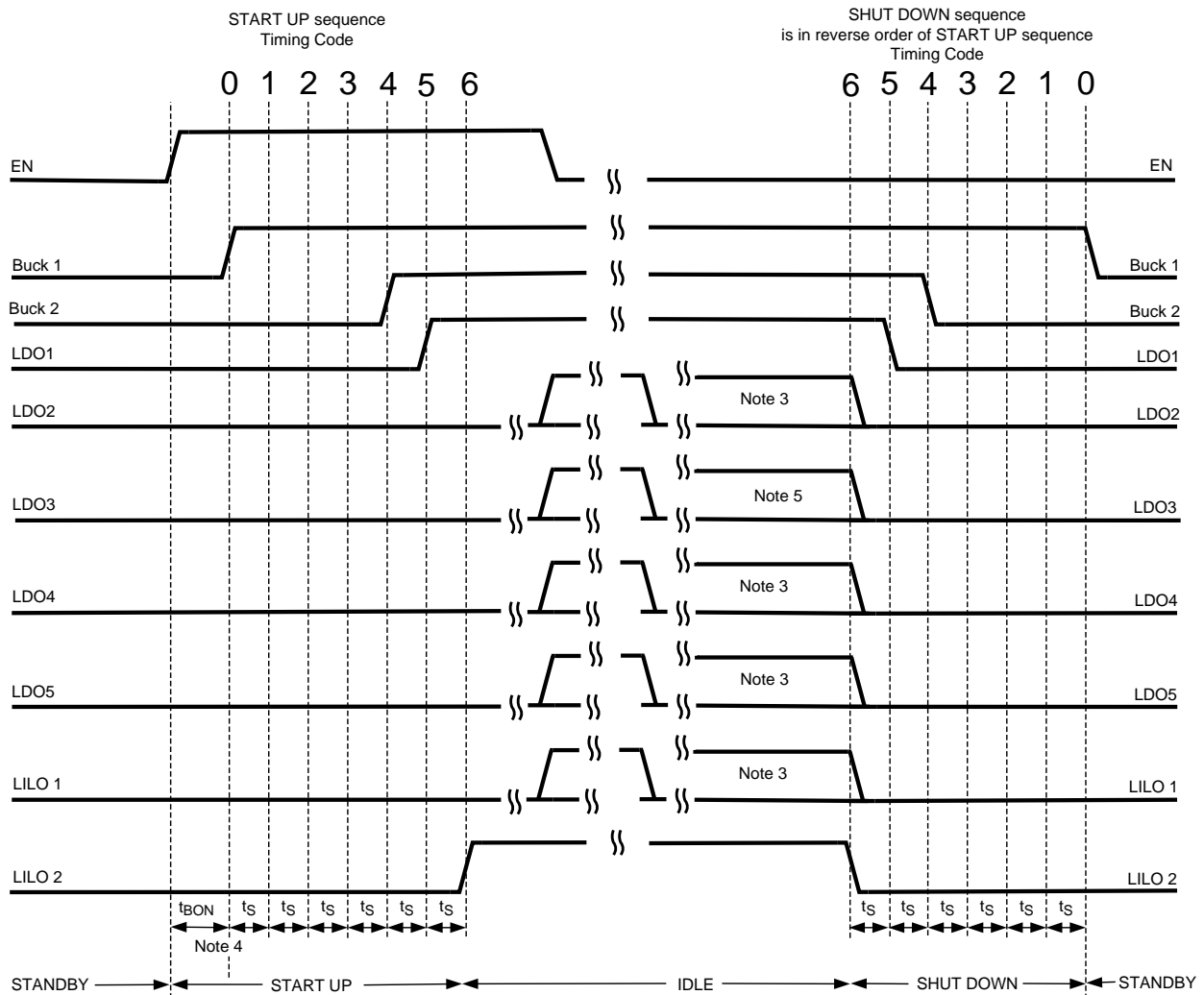
Note 2 The timing showed here define time points when LDOs and BUCK are enabled/disabled. Enabling /disabling process duration depends on voltages and loading conditions. Buck startup duration is typically 170 μ s. LDO startup duration is typically 35 μ s. For details please see LDOs and BUCK Electrical Specifications.

Note 3 LDO2, 4, 5 and LILO1 are disabled. If they are enabled via Serial Interface and the startup sequence is not changed, then they will be disabled, with no delay, from falling edge of EN-pin.

Note 4 At this time point registers are reset to POR default values.

Note 5 LDO3 is enabled by LDO3_EN (or via serial interface). If this input is high when PWR_ON goes high then this output turns on after $t_s = 6$.

Figure 10. LP8725-B Startup and Shutdown Sequence if CONFIG=GND, DEFSEL=VIN1 or DEFSEL=GND Note 1, Note 2



All timing is typical.

t_{BON} 75 μ s - Reference and bias turn ON.

t_s Programmable time steps. (Typically 64 μ s/step.) Time step accuracy is defined by OSC frequency accuracy.

Note 1 STARTUP and SHUT DOWN sequences are defined by registers. Sequences given here are valid if there the registers are not rewritten via Serial Interface.

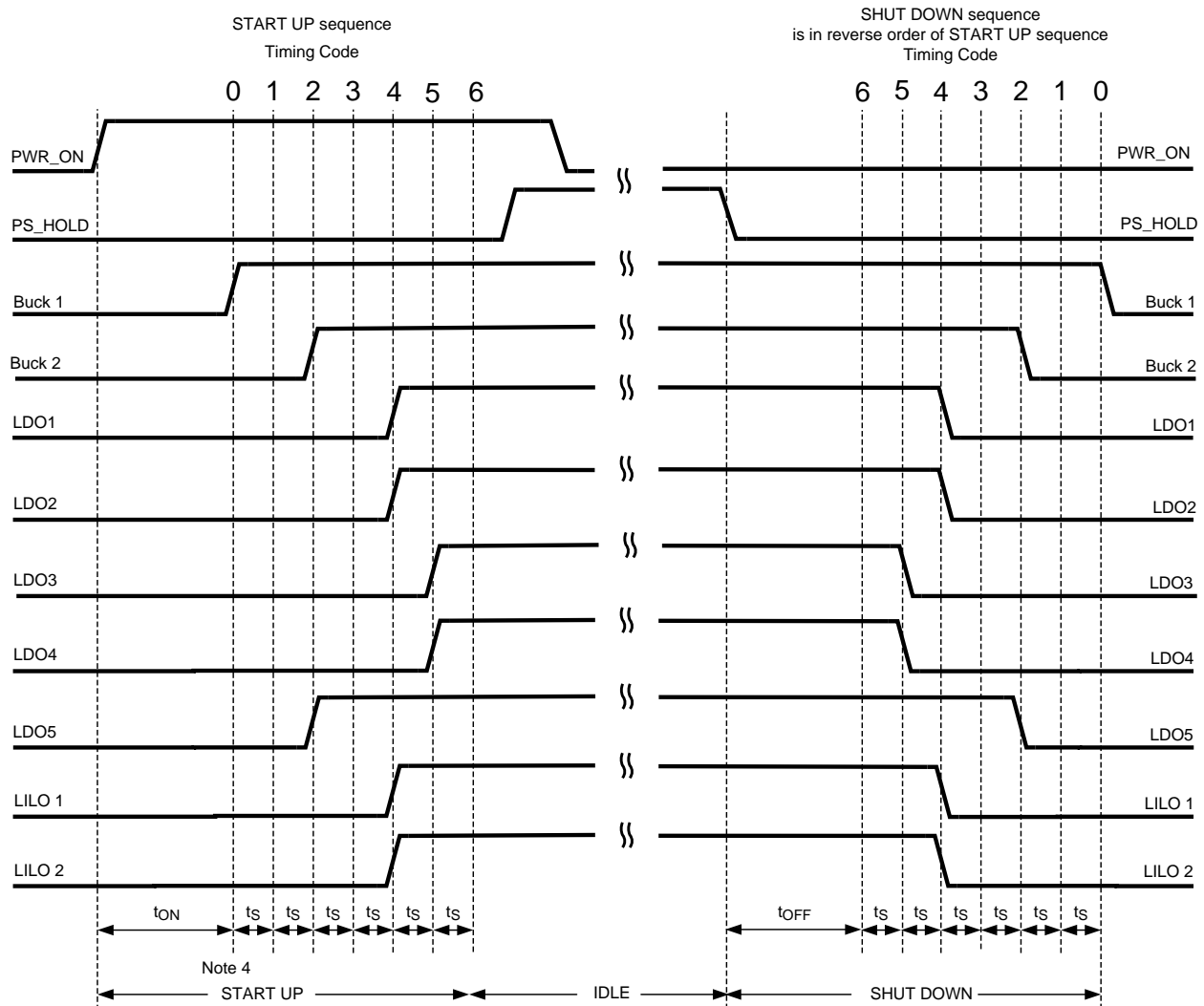
Note 2 The timing showed here define time points when LDOs and BUCK are enabled/disabled. Enabling /disabling process duration depends on voltages and loading conditions. Buck startup duration is typically 170 μ s. LDO startup duration is typically 35 μ s. For details please see LDOs and BUCK Electrical Specifications.

Note 3 LDO2, 4, 5 and LILO1 are disabled. If they are enabled via Serial Interface and the startup sequence is not changed, then they will be disabled, with no delay, from falling edge of EN-pin.

Note 4 At this time point registers are reset to POR default values.

Note 5 LDO3 is enabled by LDO3_EN (or via serial interface). If this input is high when PWR_ON goes high then this output turns on after $t_s= 6$.

Figure 11. LP8725-C Startup and Shutdown Sequence if CONFIG=VIN1, DEFSEL=VIN1 or DEFSEL=GND Note 1, Note 2



All timing is typical.

$t_{ON/OFF}$ 30 ms typ. de-bounce times.

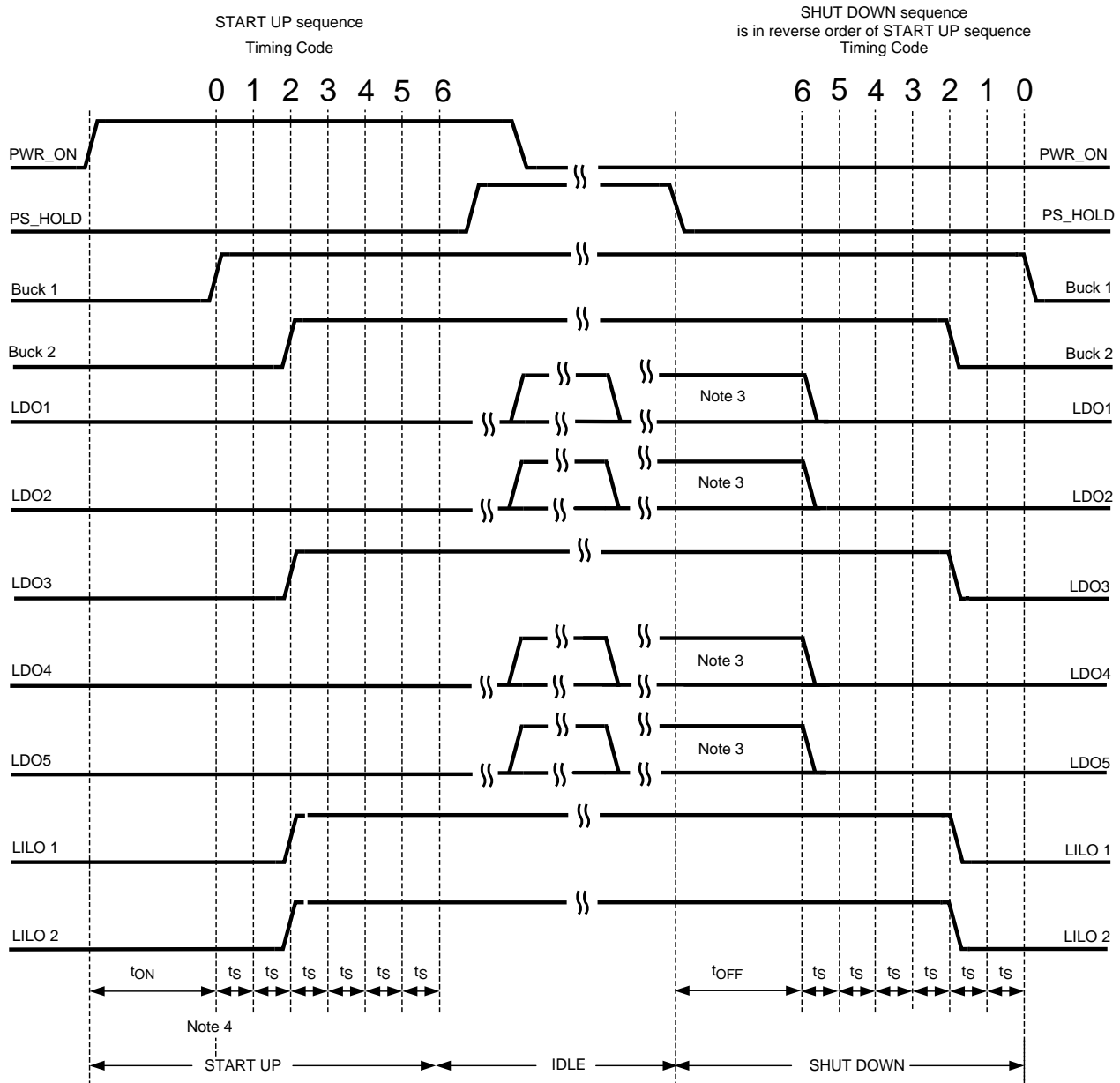
t_s Programmable time steps. (Typically 64 μ s/step.) Time step accuracy is defined by OSC frequency accuracy.

Note 1 STARTUP and SHUTDOWN sequences are defined by registers. Sequences given here are valid if there the registers are not rewritten via Serial Interface.

Note 2 The timing showed here define time points when LDOs and BUCK are enabled/disabled. Enabling /disabling process duration depends on voltages and loading conditions. Buck startup duration is typically 170 μ s. LDO startup duration is typically 35 μ s. For details please see LDOs and BUCK Electrical Specifications.

Note 4 At this time point registers are reset to POR default values.

Figure 12. LP8725-D Startup and Shutdown Sequence if CONFIG=VIN1, DEFSEL=VIN1 or DEFSEL=GND Note 1, Note 2



All timing is typical.

$t_{ON/OFF}$ 30 ms typ. de-bounce times.

t_S Programmable time steps. (Typically 64 μ s/step.) Time step accuracy is defined by OSC frequency accuracy.

Note 1 STARTUP and SHUTDOWN sequences are defined by registers. Sequences given here are valid if there the registers are not rewritten via Serial Interface.

Note 2 The timing showed here define time points when LDOs and BUCK are enabled/disabled. Enabling /disabling process duration depends on voltages and loading conditions. Buck startup duration is typically 170 μ s. LDO startup duration is typically 35 μ s. For details please see LDOs and BUCK Electrical Specifications.

Note 3 LDO1, 2, 4, 5 are disabled. If they are enabled via Serial Interface and the startup sequence is not changed, then they will be disabled, with no delay, from falling edge of EN-pin.

Note 4 At this time point registers are reset to POR default values.

Note 5 LDO3 is enabled by LDO3_EN (or via serial interface). If this input is high when PWR_ON goes high then this output turns on after $t_S=6$.

Table 3. Default Output Voltages⁽¹⁾⁽²⁾

Output	Max Current (mA)	Voltage Range (V)	Default output Voltage [V] and default ON/OFF (PWR_ON/EN=1)	
			DEFSEL = VIN1	DEFSEL = GND
BUCK1	800	0.8 to 3.0	1.0*/1.2** ON	1.2*/1.0** ON
BUCK2	600	0.8 to 3.0	1.8*/1.8** ON	1.8*/1.8** ON
LDO1	300	1.2 to 3.3	2.8 ON	2.6 ON
LDO2	300	1.2 to 3.3	1.8 ON	2.8 ON
LDO3	300	1.2 to 3.3	3.3 ON	2.8 ON
LDO4	300	1.2 to 3.3	3.3 ON	2.8 ON
LDO5	300	1.2 to 3.3	2.8 ON	2.8 ON
LIL01	300	0.8 to 3.3	1.2 ON	3.3 ON
LIL02	300	0.8 to 3.3	1.2 ON	1.2 ON

(1) These are dependent on whether DEFSEL is connected to VIN1 or GND when PWR_ON/EN=1.

(2) BUCK1 voltages are set to *BUCK1_V1 and **BUCK1_V2 as selected by DVS1_V and the DVS pin.
BUCK2 voltages are set to *BUCK2_V1 and **BUCK2_V2 as selected by DVS2_V.

Table 4. LP8725-A Alternative Part's Default Output Voltages⁽¹⁾⁽²⁾

Output	Max Current (mA)	Voltage Range (V)	Default output Voltage [V] and default ON/OFF (PWR_ON/EN=1)	
			DEFSEL = VIN1	DEFSEL = GND
BUCK1	800	0.8 to 3.0	1.1*/1.0** OFF	1.3*/1.2** ON
BUCK2	600	0.8 to 3.0	1.1*/1.0** OFF***	1.3*/1.2** ON
LDO1	300	1.2 to 3.3	2.6 ON	2.8 ON
LDO2	300	1.2 to 3.3	3.0 ON	2.8 ON
LDO3	300	1.2 to 3.3	3.3 OFF****	2.8 ON
LDO4	300	1.2 to 3.3	3.0 ON	2.8 ON
LDO5	300	1.2 to 3.3	2.8 ON	2.8 ON
LIL01	300	0.8 to 3.3	1.8 ON	1.8 ON
LIL02	300	0.8 to 3.3	1.0 ON	1.8 ON

(1) These are dependent on whether DEFSEL is connected to VIN1 or GND when PWR_ON/EN=1.

(2) BUCK1 voltages are set to *BUCK1_V1 and **BUCK1_V2 as selected by DVS1_V and the DVS pin.
BUCK2 voltages are set to *BUCK2_V1 and **BUCK2_V2 as selected by DVS2_V.

*** Only if pin B2_EN=0 if in SUB_PMU configuration

**** Only if pin LDO3_EN=0

Table 5. LP8725-B Alternative Part's Default Output Voltages⁽¹⁾⁽²⁾

Output	Max Current (mA)	Voltage Range (V)	Default output Voltage [V] and default ON/OFF (PWR_ON/EN=1)	
			DEFSEL = VIN1	DEFSEL = GND
BUCK1	800	0.8 to 3.0	1.2*/1.2** ON	1.2*/1.2** ON
BUCK2	600	0.8 to 3.0	1.8*/1.8** ON	1.8*/1.8** ON
LDO1	300	1.2 to 3.3	2.6 ON	1.8 ON
LDO2	300	1.2 to 3.3	2.8 OFF	2.8 OFF
LDO3	300	1.2 to 3.3	2.8 OFF***	2.8 OFF***
LDO4	300	1.2 to 3.3	1.2 OFF	1.2 OFF
LDO5	300	1.2 to 3.3	1.2 OFF	1.2 OFF
LIL01	300	0.8 to 3.3	2.5 OFF	2.5 OFF
LIL02	300	0.8 to 3.3	3.3 ON	3.3 ON

(1) These are dependent on whether DEFSEL is connected to VIN1 or GND when PWR_ON/EN=1.

(2) BUCK1 voltages are set to *BUCK1_V1 and **BUCK1_V2 as selected by DVS1_V and the DVS pin.
BUCK2 voltages are set to *BUCK2_V1 and **BUCK2_V2 as selected by DVS2_V.

*** Only if pin LDO3_EN=0

Table 6. LP8725-C Alternative Part's Default Output Voltages⁽¹⁾

Output	Max Current (mA)	Voltage Range (V)	Default output Voltage [V] and default ON/OFF (PWR_ON/EN=1)	
			DEFSEL = VIN1	DEFSEL = GND
BUCK1	800	0.8 to 3.0	1.2 ON	1.2 ON
BUCK2	600	0.8 to 3.0	1.8 ON	1.8 ON
LDO1	300	1.2 to 3.3	2.6 ON	2.6 ON
LDO2	300	1.2 to 3.3	2.8 ON	2.8 ON
LDO3	300	1.2 to 3.3	2.8 ON	2.8 ON
LDO4	300	1.2 to 3.3	2.5 ON	2.5 ON
LDO5	300	1.2 to 3.3	3.3 ON	3.3 ON
LIL01	300	0.8 to 3.3	1.2 ON	1.2 ON
LIL02	300	0.8 to 3.3	1.2 ON	1.2 ON

(1) These are dependent on whether DEFSEL is connected to VIN1 or GND when PWR_ON/EN=1.

Table 7. LP8725-D Alternative Part's Default Output Voltages⁽¹⁾⁽²⁾

Output	Max Current (mA)	Voltage Range (V)	Default output Voltage [V] and default ON/OFF (PWR_ON/EN=1)	
			DEFSEL = VIN1	DEFSEL = GND
BUCK1	800	0.8 to 3.0	1.3*/1.3** ON	1.3*/1.3** ON
BUCK2	800	0.8 to 3.0	1.8*/1.8** ON	1.8*/1.8** ON
LDO1	300	1.2 to 3.3	2.8 OFF	2.8 OFF
LDO2	300	1.2 to 3.3	1.8 OFF	1.8 OFF
LDO3	300	1.2 to 3.3	1.8 ON	1.8 ON
LDO4	300	1.2 to 3.3	3.0 OFF	3.0 OFF
LDO5	300	1.2 to 3.3	1.8 OFF	1.2 OFF
LIL01	300	0.8 to 3.3	3.0 ON	3.0 ON
LIL02	300	0.8 to 3.3	3.0 ON	3.0 ON

(1) These are dependent on whether DEFSEL is connected to VIN1 or GND when PWR_ON/EN=1.

(2) BUCK1 voltages are set to *BUCK1_V1 and **BUCK1_V2 as selected by DVS1_V and the DVS pin.
BUCK2 voltages are set to *BUCK2_V1 and **BUCK2_V2 as selected by DVS2_V.



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ABSOLUTE MAXIMUM RATINGS^{(1) (2)}

V_{IN1}		-0.3V to +6V
V_{IN2} , V_{IN3} , $V_{INLILO1}$, $V_{INLILO2}$, V_{INB1} , V_{INB2}		-0.3V to $V_{IN1}+0.3V$ and $<6.0V$
Logic and control pins: Voltage to GND		-0.3V to $V_{IN1}+0.3V$ and $<6.0V$
Continuous Power Dissipation ⁽³⁾		Internally Limited
Junction Temperature (T_{J-MAX})		150°C
Storage Temperature Range		-65 to 150°C
ESD Rating ⁽⁴⁾	Human Body Model	2kV
	Machine Model	200V

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltages are with respect to the potential at the GND pin.
- (3) Internal thermal shutdown circuitry protects the device from permanent damage. Thermal shutdown engages at $T_J = 150^\circ\text{C}$ (typ.) and disengages at $T_J = 130^\circ\text{C}$.
- (4) The human-body model is 100 pF discharged through 1.5 k Ω . The machine model is a 200 pF capacitor discharged directly into each pin, MIL-STD-883 3015.7.

OPERATING RATINGS^{(1) (2)}

V_{IN1}		2.6 to 4.5V
V_{IN2} , V_{IN3} , V_{INB1} , V_{INB2}		2.6V to V_{IN1}
$V_{INLILO1}$, $V_{INLILO2}$		1.8V to V_{IN1}
All input-only pins		0V to V_{IN1}
Junction Temperature (T_J)		-40 to 125°C
Ambient Temperature (T_A) ⁽³⁾		-40 to 85°C
Maximum Power Dissipation ($T_A = 70^\circ\text{C}$)		1.3 W

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltages are with respect to the potential at the GND pin.
- (3) In applications where high power dissipation and/or poor package resistance is present, the maximum ambient temperature may have to be de-rated. Maximum ambient temperature (T_{A-MAX}) is dependent on the maximum operating junction temperature (T_{J-MAX}). The maximum power dissipation of the device in the application (P_{D-MAX}) and the junction to ambient thermal resistance of the package (θ_{JA}) in the application, as given by the following equation: $T_{A-MAX} = T_{J-MAX} (\theta_{JA} \times P_{D-MAX})$. Due to the pulsed nature of testing the part, the temp in the Electrical Characteristic table is specified as $T_A = T_J$.

THERMAL PROPERTIES

Junction-to-Ambient Thermal Resistance (θ_{JA}) ⁽¹⁾ , θ_{JA} 4-Layer JEDEC Board ⁽²⁾	41°C/W
----------------------------------------------------------------------------------------------------------------------------	--------

- (1) In applications where high power dissipation and/or poor package resistance is present, the maximum ambient temperature may have to be de-rated. Maximum ambient temperature (T_{A-MAX}) is dependent on the maximum operating junction temperature (T_{J-MAX}). The maximum power dissipation of the device in the application (P_{D-MAX}) and the junction to ambient thermal resistance of the package (θ_{JA}) in the application, as given by the following equation: $T_{A-MAX} = T_{J-MAX} (\theta_{JA} \times P_{D-MAX})$. Due to the pulsed nature of testing the part, the temp in the Electrical Characteristic table is specified as $T_A = T_J$.
- (2) Junction-to-ambient thermal resistance is highly application and board layout dependent. In applications where high power dissipation exists, special care must be given to thermal dissipation issues in board design.

CURRENT CONSUMPTION

Unless otherwise noted, $V_{IN1}=V_{IN2}=V_{IN3}=V_{INB1}=V_{INB2}=V_{INL1O1}=V_{INL1O2}=3.6V$; $C_{LDOX}=1\mu F$; $C_{BUCKOUT}=C_{BUCKIN}=4.7\mu F$; $C_{VIN1-3}=C_{VINL1O1}=C_{VINL1O2}=2.2\mu F$. Typical values and limits appearing in normal type apply for $T_J=25^\circ C$. Limits appearing in **boldface** type apply over the entire junction temperature range for operation, $T_J = -40$ to $+125^\circ C$. ⁽¹⁾

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$I_{Q(STANDBY)}$	Standby Current	All outputs disabled EN = 0		3.3	8	μA
$I_{Q(SLEEP)}$	Current in SLEEP Mode at no load	Outputs disabled via control registers		50	80	
		Only Buck1 and LDO1 enabled		95		
		All outputs enabled		205	280	
$I_{Q(IDLE)}$	Current at no load	Outputs disabled via control registers		145	210	
		Only Buck1 and LDO1 enabled		205		
		All outputs enabled		420	600	

(1) Min and Max limits are specified by design, test or statistical analysis. Typical numbers are not verified, but do represent the most likely norm.

THERMAL SHUTDOWN

The Thermal Shutdown (TSD) function monitors the chip temperature (T_J) to protect the chip from temperature damage caused, e.g., by excessive power dissipation. ⁽¹⁾

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
	TSD			160		°C
	TSD Hysteresis			20		°C

(1) Min and Max limits are specified by design, test or statistical analysis. Typical numbers are not verified, but do represent the most likely norm.

UNDER-VOLTAGE LOCK OUT

This device has Under-Voltage Lock Out (UVLO) that checks VIN1-pin voltage before starting Power On sequence. UVLO is also checked during Power On sequence. If the VDD voltage is less than UVLO threshold the PMU will not Power On. After the PMU successfully passed Power On sequence UVLO is not monitored. ⁽¹⁾

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{UVLO}	UVLO Threshold V_{IN1} rising	CONFIG = 0		2.3		V
		CONFIG = 1	2.825	3.0	3.185	
	Hysteresis	CONFIG = 0		400		mV
		CONFIG = 1		800		

(1) Min and Max limits are specified by design, test or statistical analysis. Typical numbers are not verified, but do represent the most likely norm.

LOGIC AND CONTROL

Unless otherwise noted, $V_{IN1}=V_{IN2}=V_{IN3}=V_{INB1}=V_{INB2}=V_{INL1O1}=V_{INL1O2}=3.6V$; $C_{LDOX}=1\mu F$; $C_{BUCKOUT}=C_{BUCKIN}=4.7\mu F$; $C_{VIN1-3}=C_{VINL1O1}=C_{VINL1O2}=2.2\mu F$. Typical values and limits appearing in normal type apply for $T_J=25^\circ C$. Limits appearing in **boldface** type apply over the entire junction temperature range for operation, $T_J = -40$ to $+125^\circ C$. ⁽¹⁾

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Logic and Control Inputs						
V_{IL}	Input Low Level	EN, SCL, SDA, DVS, PS_HOLD, PWR_ON, BUCK2_EN, LDO3_EN			0.4	V
V_{IH}	Input High Level	EN, SCL, SDA, DVS, PS_HOLD, PWR_ON, BUCK2_EN, LDO3_EN	1.2			V
I_{IL}	Input Low Level Current	EN, SCL, SDA, DVS, PS_HOLD, PWR_ON, DVS, DEFSEL, CONFIG, BUCK2_EN, LDO3_EN $V_{IL} = 0V$		0	2	μA

(1) Min and Max limits are specified by design, test or statistical analysis. Typical numbers are not verified, but do represent the most likely norm.

LOGIC AND CONTROL (continued)

Unless otherwise noted, $V_{IN1}=V_{IN2}=V_{IN3}=V_{INB1}=V_{INB2}=V_{INL1O1}=V_{INL1O2}=3.6V$; $C_{LODX}=1\mu F$; $C_{BUCKOUT}=C_{BUCKIN}=4.7\mu F$, $C_{VIN1-3}=C_{VINL1O1}C_{VINL1O2}=2.2\mu F$. Typical values and limits appearing in normal type apply for $T_J=25^\circ C$. Limits appearing in **boldface** type apply over the entire junction temperature range for operation, $T_J = -40$ to $+125^\circ C$.⁽¹⁾

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I_{IH}	Input High Level Current	PS_HOLD, DEFSEL, CONFIG, DVS $V_{IH} = V_{IN1}$		0	2	
R_{PD}	Pull Down Resistance	From EN, PWR_ON, B2_EN, and LDO3_EN		500		k Ω
Logic and Control Outputs						
V_{OL}	Output Low Level	SDA, RESET_N $I_{OUT} = 2mA$		0.14	0.3	V
I_{OH}	Output High Level	SDA, RESET_N have Open drain outputs $V_{OH} = V_{IN1}$		0	2	μA

BUCK CONVERTERS

Unless otherwise noted, $V_{IN1}=V_{IN2}=V_{IN3}=V_{INB1}=V_{INB2}=V_{INL1O1}=V_{INL1O2}=3.6V$; $C_{LODX}=1\mu F$; $C_{BUCKOUT}=C_{BUCKIN}=4.7\mu F$, $C_{VIN1-3}=C_{VINL1O1}C_{VINL1O2}=2.2\mu F$. Typical values and limits appearing in normal type apply for $T_J=25^\circ C$. Limits appearing in **boldface** type apply over the entire junction temperature range for operation, $T_J = -40$ to $+125^\circ C$.^{(1) (2)}

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{FB}	BUCK1 Feedback Voltage	$V_{OUT} = 1.8V$	-2		+2	%
	BUCK2 Feedback Voltage		-3		+3	
$R_{DSON(P)}$	Pin-Pin resistance for PFET	$I_{OUT} = 200 mA$		265		m Ω
$R_{DSON(N)}$	Pin-Pin resistance for NFET	$I_{OUT} = -200 mA$		150		m Ω
I_{LIM}	Switch Peak Current Limit	Open-loop, programmable: 250 mA max I_{OUT} typ 450 mA max I_{OUT} typ 600 mA max I_{OUT} typ 800 mA max I_{OUT} typ		460		mA
				780		
			750	1050	1500	
				1370		
t_{STUP}	Startup Time	$I_{OUT} = 0mA$ to 100 mA		170		μs
f_{SW}	Switching Frequency		3.6	4.1	4.4	MHz

- (1) Min and Max limits are specified by design, test or statistical analysis. Typical numbers are not verified, but do represent the most likely norm.
- (2) The parameters in the electrical characteristic table are tested under open loop conditions at $V_{IN} = 3.6V$ unless otherwise specified. For performance over the input voltage range and closed loop condition, refer to the datasheet curves.

DIGITAL LDOs (1, 2, 3)

Unless otherwise noted, $V_{IN1}=V_{IN2}=V_{IN3}=V_{INB1}=V_{INB2}=V_{INL1O1}=V_{INL1O2}=3.6V$; $C_{LODX}=1\mu F$; $C_{BUCKOUT}=C_{BUCKIN}=4.7\mu F$, $C_{VIN1-3}=C_{VINL1O1}C_{VINL1O2}=2.2\mu F$. Typical values and limits appearing in normal type apply for $T_J=25^\circ C$. Limits appearing in **boldface** type apply over the entire junction temperature range for operation, $T_J = -40$ to $+125^\circ C$.⁽¹⁾

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{OUT}	LDO1 Output Voltage Accuracy	$I_{OUT} = 1mA$, $V_{OUT} = 2.8V$	-1.5		+1.5	%
			-2		+2	
	LDOs 2 & 3 Output Voltage Accuracy		-2		+2	
			-2.5		+2.5	
ΔV_{OUT}	Line Regulation	$V_{OUT} + 0.5V \leq V_{IN2} \leq 4.5V$ $I_{OUT} = 1mA$ ⁽²⁾		2		mV
	Load Regulation	$1 < I_{OUT} < 300 mA$		2		

- (1) Min and Max limits are specified by design, test or statistical analysis. Typical numbers are not verified, but do represent the most likely norm.
- (2) The minimum input voltage equals $V_{OUT} (nom) + 0.5V$ or $2.5V$, which ever is greater.

DIGITAL LDOs (1, 2, 3) (continued)

Unless otherwise noted, $V_{IN1}=V_{IN2}=V_{IN3}=V_{INB1}=V_{INB2}=V_{INL1LO1}=V_{INL1LO2}=3.6V$; $C_{LODX}=1\mu F$; $C_{BUCKOUT}=C_{BUCKIN}=4.7\mu F$, $C_{VIN1-3}=C_{VINL1LO1}C_{VINL1LO2}=2.2\mu F$. Typical values and limits appearing in normal type apply for $T_J=25^\circ C$. Limits appearing in **boldface** type apply over the entire junction temperature range for operation, $T_J=-40$ to $+125^\circ C$. ⁽¹⁾

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{DO}	Dropout Voltage	$I_{OUT} = 300\text{ mA}$ Nominal $V_{OUT} = 2.8V$ ⁽³⁾		190	270	mV
I_{OUT}	Output Current		0		300	mA
I_{SLEEP}	Max Output Current in Sleep Mode				1	mA
I_{SC}	Output Current Limit	$V_{OUT} = 0V$		650		mA
e_N	Output Voltage Noise	$10\text{ Hz} \leq f \leq 100\text{ KHz}$ $I_{OUT} = 300\text{ mA}$		35		μV_{RMS}
PSRR	Power Supply Rejection Ratio	$f \leq 10\text{ KHz}$, $I_{OUT} = 20\text{ mA}$		65		dB
t_{STUP}	Startup Time	$I_{OUT} = 0\text{ mA}$ to 300 mA in Idle mode.		20		μs
V_{OS}	Start-up Overshoot	$I_{OUT} = 300\text{ mA}$ ⁽⁴⁾			30	mV
C_{OUT}	External Output Capacitance for Stability	⁽⁴⁾	0.5	1	20	μF

(3) Dropout voltage is the voltage difference between the input and the output at which the output voltage drops to 100 mV below its nominal value.

(4) This specification is guaranteed by design.

LOW-NOISE ANALOG LDOs (4, 5)

Unless otherwise noted, $V_{IN1}=V_{IN2}=V_{IN3}=V_{INB1}=V_{INB2}=V_{INL1LO1}=V_{INL1LO2}=3.6V$; $C_{LODX}=1\mu F$; $C_{BUCKOUT}=C_{BUCKIN}=4.7\mu F$, $C_{VIN1-3}=C_{VINL1LO1}C_{VINL1LO2}=2.2\mu F$. Typical values and limits appearing in normal type apply for $T_J=25^\circ C$. Limits appearing in **boldface** type apply over the entire junction temperature range for operation, $T_J=-40$ to $+125^\circ C$. ⁽¹⁾

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{OUT}	Output Voltage Accuracy	$I_{OUT} = 1\text{ mA}$, $V_{OUT} = 2.8V$	-2		+2	%
			-2.5		+2.5	
ΔV_{OUT}	Line Regulation	$V_{OUT} + 0.5V \leq V_{IN3} \leq 4.5V$ $I_{OUT} = 1\text{ mA}$ ⁽²⁾		1		mV
	Load Regulation	$1 < I_{OUT} < 300\text{ mA}$		1		
V_{DO}	Dropout Voltage	$I_{OUT} = 300\text{ mA}$ Nominal $V_{OUT} = 2.8V$ ⁽³⁾		220	310	mV
I_{OUT}	Output Current		0		300	mA
I_{SLEEP}	Max Output Current in Sleep Mode				1	mA
I_{SC}	Output Current Limit	$V_{OUT} = 0V$		625		mA
e_N	Output Voltage Noise	$10\text{ Hz} \leq f \leq 100\text{ KHz}$ $I_{OUT} = 300\text{ mA}$	10	10		μV_{RMS}
PSRR	Power Supply Rejection Ratio	$f \leq 10\text{ KHz}$, $I_{OUT} = 20\text{ mA}$		75		dB
t_{STUP}	Startup Time	$I_{OUT} = 0\text{ mA}$ to 300 mA in Idle mode.		35		μs
V_{OS}	Start-up Overshoot	$I_{OUT} = 300\text{ mA}$ ⁽⁴⁾			30	mV
C_{OUT}	External Output Capacitance for Stability	⁽⁴⁾	0.5	1	20	μF

(1) Min and Max limits are specified by design, test or statistical analysis. Typical numbers are not verified, but do represent the most likely norm.

(2) The minimum input voltage equals $V_{OUT}(\text{nom}) + 0.5V$ or $2.5V$, which ever is greater.

(3) Dropout voltage is the voltage difference between the input and the output at which the output voltage drops to 100 mV below its nominal value.

(4) This specification is guaranteed by design.

LOW-INPUT LOW-OUTPUT LDO (L1LO1, L1LO2)

Unless otherwise noted, $V_{IN1}=V_{IN2}=V_{IN3}=V_{INB1}=V_{INB2}=V_{INL1LO1}=V_{INL1LO2}=3.6V$; $C_{LODX}=1\mu F$; $C_{BUCKOUT}=C_{BUCKIN}=4.7\mu F$, $C_{VIN1-3}=C_{VINL1LO1}C_{VINL1LO2}=2.2\mu F$. Typical values and limits appearing in normal type apply for $T_J=25^\circ C$. Limits appearing in **boldface** type apply over the entire junction temperature range for operation, $T_J=-40$ to $+125^\circ C$. ⁽¹⁾

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{OUT}	L1LO1 Output Voltage Accuracy	$I_{OUT} = 1mA, V_{OUT} = 1.8V$	-2		+2	%
			-3		+3	
	L1LO2 Output Voltage Accuracy		-3		+3	
			-4		+4	
ΔV_{OUT}	Line Regulation	$V_{OUT} + 0.5V \leq V_{L1LO} \leq 4.5V$ $I_{OUT} = 1mA$		1		mV
	Load Regulation	$1 < I_{OUT} < 300 mA$		5		
V_{DO}	Dropout Voltage	$I_{OUT} = 300 mA$ Nominal $V_{OUT} = 1.8V$ ⁽²⁾		230	310	mV
I_{OUT}	Output Current		0		300	mA
I_{SLEEP}	Max Output Current in Sleep Mode				1	mA
I_{SC}	Output Current Limit	$V_{OUT} = 0V$		670		mA
e_N	Output Voltage Noise	$10 Hz \leq f \leq 100 KHz$ $I_{OUT} = 300 mA$		80		μV_{RMS}
PSRR	Power Supply Rejection Ratio	$f \leq 10 KHz, I_{OUT} = 20 mA$		60		dB
t_{STUP}	Startup Time	$I_{OUT} = 0 mA$ to $300 mA$ in Idle mode.		65		μs
V_{OS}	Start-up Overshoot	⁽³⁾			30	mV
C_{OUT}	External Output Capacitance for Stability	⁽³⁾	0.5	1	20	μF

- (1) Min and Max limits are specified by design, test or statistical analysis. Typical numbers are not verified, but do represent the most likely norm.
- (2) Dropout voltage is the voltage difference between the input and the output at which the output voltage drops to 100 mV below its nominal value.
- (3) This specification is guaranteed by design.

LP8725 CONTROL REGISTERS

Table 8. Control Registers

ADDR	Register Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
0x00	GENERAL	TIMESTEP	SHORT_TIMESTEP	0	BUCK2_EN	DVS2_V	DVS1_V	SLEEP_MODE	BUCK1_EN
0x01	LDO1	LDO1_T[2]	LDO1_T[1]	LDO1_T[0]	LDO1_V[4]	LDO1_V[3]	LDO1_V[2]	LDO1_V[1]	LDO1_V[0]
0x02	LDO2	LDO2_T[2]	LDO2_T[1]	LDO2_T[0]	LDO2_V[4]	LDO2_V[3]	LDO2_V[2]	LDO2_V[1]	LDO2_V[0]
0x03	LDO3	LDO3_T[2]	LDO3_T[1]	LDO3_T[0]	LDO3_V[4]	LDO3_V[3]	LDO3_V[2]	LDO3_V[1]	LDO3_V[0]
0x04	LDO4	LDO4_T[2]	LDO4_T[1]	LDO4_T[0]	LDO4_V[4]	LDO4_V[3]	LDO4_V[2]	LDO4_V[1]	LDO4_V[0]
0x05	LDO5	LDO5_T[2]	LDO5_T[1]	LDO5_T[0]	LDO5_V[4]	LDO5_V[3]	LDO5_V[2]	LDO5_V[1]	LDO5_V[0]
0x06	LIL01	LIL01_T[2]	LIL01_T[1]	LIL01_T[0]	LIL01_V[4]	LIL01_V[3]	LIL01_V[2]	LIL01_V[1]	LIL01_V[0]
0x07	LIL02	LIL02_T[2]	LIL02_T[1]	LIL02_T[0]	LIL02_V[4]	LIL02_V[3]	LIL02_V[2]	LIL02_V[1]	LIL02_V[0]
0x08	BUCK1 V1	BUCK1_T[2]	BUCK1_T[1]	BUCK1_T[0]	BUCK1_V1[4]	BUCK1_V1[3]	BUCK1_V1[2]	BUCK1_V1[1]	BUCK1_V1[0]
0x09	BUCK1 V2	BUCK1_CL[1]	BUCK1_CL[0]	0	BUCK1_V2[4]	BUCK1_V2[3]	BUCK1_V2[2]	BUCK1_V2[1]	BUCK1_V2[0]
0x0A	BUCK2 V1	BUCK2_T[2]	BUCK2_T[1]	BUCK2_T[0]	BUCK2_V1[4]	BUCK2_V1[3]	BUCK2_V1[2]	BUCK2_V1[1]	BUCK2_V1[0]
0x0B	BUCK2 V2	BUCK2_CL[1]	BUCK2_CL[0]	0	BUCK2_V2[4]	BUCK2_V2[3]	BUCK2_V2[2]	BUCK2_V2[1]	BUCK2_V2[0]
0x0C	BUCK CONTROL	BK2_FLAG MASK	BK1_FLAG MASK	PWM_BUCK2	PDN_BUCK2	0	0	PWM_BUCK1	PDN_BUCK1
0x0D	LDO CONTROL	LDO1_FLAG MASK	LIL02_EN	LIL01_EN	LDO5_EN	LDO4_EN	LDO3_EN	LDO2_EN	LDO1_EN
0x0E	PULL DOWN BITS	APU_TSD	PDN_LIL02	PDN_LIL01	PDN_LDO5	PDN_LDO4	PDN_LDO3	PDN_LDO2	PDN_LDO1
0x0F	STATUS BITS	REVISION[3]	REVISION[2]	REVISION[1]	REVISION[0]	LDO1_OKN	B2_OKN	B1_OKN	TSD

Table 9. Control Register Defaults

ADDR	LP8725 Defaults: DEFSEL state		LP8725-A Defaults: DEFSEL state		LP8725-B Defaults: DEFSEL state	
	VIN1	GND	VIN1	GND	VIN1	GND
0x00	0101 1001	0101 1001	0000 0000	0101 0001	1101 1101	1101 1101
0x01	1001 1001	0011 0101	0001 0101	1001 1001	1011 0101	1010 1100
0x02	1000 1100	0011 1001	0001 1101	0111 1001	1111 1001	1111 1001
0x03	1011 1111	0101 1001	1111 1111	0111 1001	1111 1001	1111 1001
0x04	1001 1111	0101 1001	0011 1101	1001 1001	1110 0000	1110 0000
0x05	1001 1001	0011 1001	0001 1001	1001 1001	1110 0000	1110 0000
0x06	1010 1000	0011 1111	0001 0000	1011 0000	1111 0111	1111 0111
0x07	0100 1000	0000 1000	0010 0100	1011 0000	1101 1111	1101 1111
0x08	0000 0100	0000 1000	1110 0110	0000 1010	0000 1000	0000 1000
0x09	1100 1000	1100 0100	1100 0100	1100 1000	1100 1000	1100 1000
0x0A	0101 0001	0011 0001	1110 0110	0000 1010	1001 0001	1001 0001
0x0B	1001 0001	1001 0001	1000 0100	1000 1000	1001 0001	1001 0001
0x0C	0111 1111	0001 0001	1101 0001	1101 0001	0001 0001	0001 0001

Table 9. Control Register Defaults (continued)

ADDR	LP8725 Defaults: DEFSEL state		LP8725-A Defaults: DEFSEL state		LP8725-B Defaults: DEFSEL state	
	VIN1	GND	VIN1	GND	VIN1	GND
0x0D	0111 1111	0111 1111	1111 1011	1111 1111	0100 0001	0100 0001
0x0E	0111 1111	0111 1111	0111 1111	0111 1111	0111 1111	0111 1111
0x0F	0000 0000	0000 0000	0000 0000	0000 0000	0000 0000	0000 0000

ADDR	LP8725-C Defaults: DEFSEL state		LP8725-D Defaults: DEFSEL state	
	VIN1	GND	VIN1	GND
0x00	1101 1101	1101 1101	1001 1101	1001 1101
0x01	1001 0101	1001 0101	1111 1001	1111 1001
0x02	1001 1001	1001 1001	1110 1100	1110 1100
0x03	1011 1001	1011 1001	0100 1100	0100 1100
0x04	1011 0100	1011 0100	1111 1101	1111 1101
0x05	0101 1111	0101 1111	1110 0000	1110 1100
0x06	1000 1000	1000 1000	0101 1101	0101 1101
0x07	1000 1000	1000 1000	0101 1101	0101 1101
0x08	0000 1000	0000 1000	0000 1010	0000 1010
0x09	1100 1000	1100 1000	1100 1010	1100 1010
0x0A	0101 0001	0101 0001	0101 0001	0101 0001
0x0B	1001 0001	1001 0001	1101 0001	1101 0001
0x0C	0001 0001	0001 0001	0001 0001	0001 0001
0x0D	0111 1111	0111 1111	0110 0100	0110 0100
0x0E	0111 1111	0111 1111	0111 1111	0111 1111
0x0F	0000 0000	0000 0000	0000 0000	0000 0000

Table 10. Register 0X00

Addr	Register	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
0x00	GENERAL	TIMESTEP	SHORT_TIMESTEP		BUCK2_EN N	DVS2_V	DVS1_V	SLEEP_MODE	BUCK1_EN

BUCK1_EN BUCK2_EN	BUCK1, BUCK2 enable control In STANDBY mode 1: During next STARTUP sequence will be enabled. 0: During next STARTUP sequence will be NOT enabled For proper operation output timing having "111 - NO startup" should have corresponding enable bit 0 (disable) In IDLE mode the bit has immediate effect. 1: Enable 0: Disable
SLEEP_MODE	LDO Sleep Control 1: SLEEP mode 0: normal
DVS1_V	1: drive buck voltage to value stored in BUCK1_V1[4:0] 0: Buck output voltage controlled by external DVS pin.
DVS2_V	1: drive buck voltage to value stored in BUCK2_V1[4:0] 0: Buck output voltage to value stored in BUCK2_V2[4:0]
SHORT_TIMESTEP TIMESTEP	TIMESTEP = 0 SHORT_TIMESTEP = 0 — time step $t_s = 32 \mu s$ SHORT_TIMESTEP = 1 — time step $t_s = 64 \mu s$ TIMESTEP = 1 SHORT_TIMESTEP = 0 — time step $t_s = 128 \mu s$ SHORT_TIMESTEP = 1 — time step $t_s = 256 \mu s$

Table 11. Registers 0x01-0x05, 0x06-0x07, 0x08-0x0B

Addr	Register	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
0x01	LDO1 O/P	LDO1 T[2]	LDO1 T[1]	LDO1 T[0]	LDO1 V[4]	LDO1 V[3]	LDO1 V[2]	LDO1 V[1]	LDO1 V[0]
0x02	LDO2 O/P	LDO2 T[2]	LDO2 T[1]	LDO2 T[0]	LDO2 V[4]	LDO2 V[3]	LDO2 V[2]	LDO2 V[1]	LDO2 V[0]
0x03	LDO3 O/P	LDO3 T[2]	LDO3 T[1]	LDO3 T[0]	LDO3 V[4]	LDO3 V[3]	LDO3 V[2]	LDO3 V[1]	LDO3 V[0]
0x04	LDO4 O/P	LDO4 T[2]	LDO4 T[1]	LDO4 T[0]	LDO4 V[4]	LDO4 V[3]	LDO4 V[2]	LDO4 V[1]	LDO4 V[0]
0x05	LDO5 O/P	LDO5 T[2]	LDO5 T[1]	LDO5 T[0]	LDO5 V[4]	LDO5 V[3]	LDO5 V[2]	LDO5 V[1]	LDO5 V[0]
0x06	LIL01 O/P	LIL01_ T[2]	LIL01_ T[1]	LIL01_ T[0]	LIL01_ V[4]	LIL01_ V[3]	LIL01_ V[2]	LIL01_ V[1]	LIL01_ V[0]
0x07	LIL02 O/P	LIL02_ T[2]	LIL02_ T[1]	LIL02_ T[0]	LIL02_ V[4]	LIL02_ V[3]	LIL02_ V[2]	LIL02_ V[1]	LIL02_ V[0]
0x08	BUCK1 O/P1	BUCK1_ T[2]	BUCK1_ T[1]	BUCK1_ T[0]	BUCK1_ V1[4]	BUCK1_ V1[3]	BUCK1_ V1[2]	BUCK1_ V1[1]	BUCK1_ V1[0]
0x09	BUCK1 O/P2	BUCK1_ CL[1]	BUCK1_ CL[0]		BUCK1_ V2[4]	BUCK1_ V2[3]	BUCK1_ V2[2]	BUCK1_ V2[1]	BUCK1_ V2[0]
0x0A	BUCK2 O/P1	BUCK2_ T[2]	BUCK2_ CL[2]	BUCK2_ T[0]	BUCK2_ V1[4]	BUCK2_ V1[3]	BUCK2_ V1[2]	BUCK2_ V1[1]	BUCK2_ V1[0]
0x0B	BUCK2 O/P2	BUCK2_ CL[1]	BUCK2_ CL[0]		BUCK2_ V2[4]	BUCK2_ V2[3]	BUCK2_ V2[2]	BUCK2_ V2[1]	BUCK2_ V2[0]

Registers 0x01 - 0x05	Output Voltage Selection							
LDO1_V[4:0]	00000	1.20V	01000	1.60V	10000	2.10V	11000	2.75V
LDO2_V[4:0]	00001	1.25V	01001	1.65V	10001	2.20V	11001	2.80V
LDO3_V[4:0]	00010	1.30V	01010	1.70V	10010	2.30V	11010	2.85V
LDO4_V[4:0]	00011	1.35V	01011	1.75V	10011	2.40V	11011	2.90V
LDO5_V[4:0]	00100	1.40V	01100	1.80V	10100	2.50V	11100	2.95V
	00101	1.45V	01101	1.85V	10101	2.60V	11101	3.00V
	00110	1.50V	01110	1.90V	10110	2.65V	11110	3.10V
	00111	1.55V	01111	2.00V	10111	2.70V	11111	3.30V

Registers 0x06 - 0x07	Output Voltage Selection							
LIL01_V[4:0]	00000	0.80V	01000	1.20V	10000	1.80V	11000	2.60V
LIL02_V[4:0]	00001	0.85V	01001	1.25V	10001	1.90V	11001	2.70V
	00010	0.90V	01010	1.30V	10010	2.00V	11010	2.80V
	00011	0.95V	01011	1.35V	10011	2.10V	11011	2.85V
	00100	1.00V	01100	1.40V	10100	2.20V	11100	2.90V
	00101	1.05V	01101	1.50V	10101	2.30V	11101	3.00V
	00110	1.10V	01110	1.60V	10110	2.40V	11110	3.10V
	00111	1.15V	01111	1.70V	10111	2.50V	11111	3.30V

Registers 0x08 - 0x0B	Output Voltage Selection							
BUCK1_V[4:0]	00000	0.80V	01000	1.20V	10000	1.75V	11000	2.40V
BUCK2_V[4:0]	00001	0.85V	01001	1.25V	10001	1.80V	11001	2.50V
	00010	0.90V	01010	1.30V	10010	1.85V	11010	2.60V
	00011	0.95V	01011	1.35V	10011	1.90V	11011	2.70V
	00100	1.00V	01100	1.40V	10100	2.00V	11100	2.80V
	00101	1.05V	01101	1.50V	10101	2.10V	11101	2.85V
	00110	1.10V	01110	1.60V	10110	2.20V	11110	2.90V
	00111	1.15V	01111	1.70V	10111	2.30V	11111	3.00V

Registers 0x01 - 0x08, 0x0A	Startup Delay Selection
LDO1_T[2:0] LDO2_T[2:0] LDO3_T[2:0] LDO4_T[2:0] LDO5_T[2:0] LIL01_T[2:0] LIL02_T[2:0] BUCK1_T[2:0] BUCK2_T[2:0]	000 - startup delay 0 001 - startup delay = 1 * time step t_s 010 - startup delay = 2 * time step t_s 011 - startup delay = 3 * time step t_s 100 - startup delay = 4 * time step t_s 101 - startup delay = 5 * time step t_s 110 - startup delay = 6 * time step t_s 111 - NO startup For proper startup operation "NO startup" <111> should have the corresponding enable bit in registers 0x00 & 0x0D set to 0 (disable)

Registers 0x09, 0x0B	Buck Current Limit Selection
BUCK1_CL[1:0] BUCK2_CL[1:0]	00 - 460 mA peak (250 mA max I_{OUT}) 01 - 780 mA peak (450 mA max I_{OUT}) 10 - 1050 mA peak (600 mA max I_{OUT}) 11 - 1370 mA peak (800 mA max I_{OUT})

Register 0x0C	
PDN_BUCK1 PDN_BUCK2	Pull-down BUCK1/2: 1 - Pull down enabled 0 - Pull down disabled
PWM_BUCK1 PWM_BUCK2	1 - BUCK1/2 is forced to work in PWM mode 0 - BUCK1/2 works in automatic ECO/PWM selection mode
BK1_FLAG MASK BK2_FLAG MASK	1 - Mask the BUCK OK flag 0 - No masking of BUCK OK flag

Register 0x0D	LDO Enable Control	
LDO1_EN LDO2_EN LDO3_EN LDO4_EN LDO5_EN LIL01_EN LIL02_EN	In STANDBY mode: 1 - During next STARTUP sequence will be enabled. 0 - During next startup sequence will be NOT enabled.	In IDLE mode the bit has immediate effect. 1 - Enable 0 - Disable
LDO1_FLAG MASK	1- Mask the LDO1 OK flag 0 - No masking of LDO1 OK flag	

Register 0x0E	Pull Down
PDNLDO1 PDNLDO2 PDNLDO3 PDNLDO4 PDNLDO5 PDNLIL01 PDNLIL02	LDO pull-down control 1 - Pull down enabled 0 - Pull down disabled
APU_TSD	This bit defines either to reset registers or not before the PMU automatically starts startup sequence from Thermal Shutdown after cooling down if EN-pin is High. 1 - No change to registers - content stays the same as before Thermal Shutdown. 0 - If CONFIG = '1' Reset registers to default values before startup from Thermal Shutdown.

Table 12. Register 0x0F (Read Only Register)

Addr	Register	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
0x10	STATUS	REVISION[3]	REVISION[2]	REVISION[1]	REVISION[0]	LDO1_OK N	B2_OKN	B1_OKN	TSD
TSD		1 - Device is in Thermal Shutdown 0 - Device is NOT in Thermal Shutdown							
B1_OKN B2_OKN LDO1_OKN		1 - Output voltage not in regulation 0 - Output voltage in regulation							
REVISION[3:0]		LP8725 Mask set revision. To be incremented, whenever the mask set is edited.							

OPERATION DESCRIPTION

Device Information

Using voltage mode architecture with synchronous rectification, the LP8725 has the ability to deliver up to 800 mA per DC-DC convertor depending on the input voltage and output voltage, ambient temperature, and the inductor chosen.

There are two modes of operation depending on the current required - PWM (Pulse Width Modulation), and ECO. The device operates in PWM mode at load currents of approximately 75 mA (typ.) or higher. Lighter output current loads cause the device to automatically switch into ECO mode for reduced current consumption.

Circuit Operation

The DC-DC convertor operates as follows. During the first portion of each switching cycle, the control block in the turns on the internal PFET switch. This allows current to flow from the input through the inductor to the output filter capacitor and load. The inductor limits the current to a ramp with a slope of $(V_{IN} - V_{OUT})/L$, by storing energy in a magnetic field. During the second portion of each cycle, the controller turns the PFET switch off, blocking current flow from the input, and then turns the NFET synchronous rectifier on. The inductor draws current from ground through the NFET to the output filter capacitor and load, which ramps the inductor current down with a slope of $-V_{OUT}/L$.

The output filter stores charge when the inductor current is high, and releases it when low, smoothing the voltage across the load. The output voltage is regulated by modulating the PFET switch on time to control the average current sent to the load. The effect is identical to sending a duty-cycle modulated rectangular wave formed by the switch and synchronous rectifier at the SW pin to a low-pass filter formed by the inductor and output filter capacitor. The output voltage is equal to the average voltage at the SW pin.

PWM Operation

During PWM operation the converter operates as a voltage-mode controller with input voltage feed forward. This allows the converter to achieve excellent load and line regulation. The DC gain of the power stage is proportional to the input voltage. To eliminate this dependence, feed forward inversely proportional to the input voltage is introduced. While in PWM mode, the output voltage is regulated by switching at a constant frequency and then modulating the energy per cycle to control power to the load. At the beginning of each clock cycle the PFET switch is turned on and the inductor current ramps up until the comparator trips and the control logic turns off the switch. The current limit comparator can also turn off the switch in case the current limit of the PFET is exceeded. Then the NFET switch is turned on and the inductor current ramps down. The next cycle is initiated by the clock turning off the NFET and turning on the PFET.

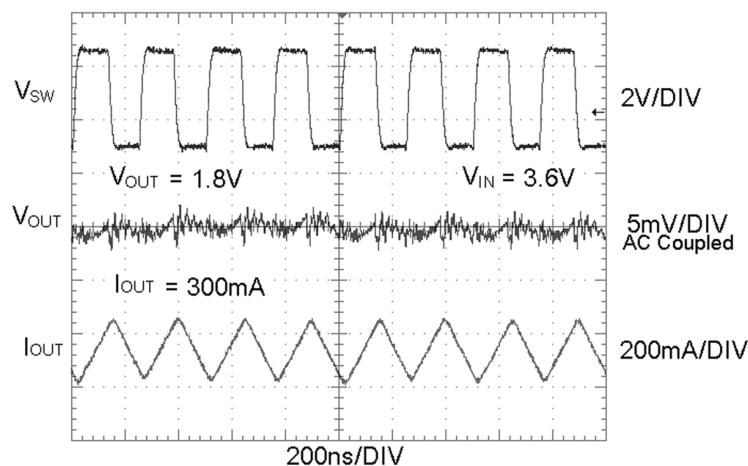


Figure 13. Typical PWM Operation

Internal Synchronous Rectification

While in PWM mode, the DC-DC converter uses an internal NFET as a synchronous rectifier to reduce rectifier forward voltage drop and associated power loss. Synchronous rectification provides a significant improvement in efficiency whenever the output voltage is relatively low compared to the voltage drop across an ordinary rectifier diode.

Current Limiting

A current limit feature allows the DC-DC converter to protect itself and external components during overload conditions. PWM mode implements current limit using an internal comparator that trips at 1.05A (typ.) assuming $I_{OUT} = 600\text{ mA}$. If the output is shorted to ground and output voltage becomes lower than 0.3V (typ.), the device enters a timed current limit mode where the switching frequency will be one fourth, and NFET synchronous rectifier is disabled, thereby preventing excess current and thermal runaway.

The current limit for each DC-DC converter is selectable via serial interface by registers 0x09 bits 6, 7 and 0x0B bits 6, 7. The current limit selected should be ~ 1.5x to 2x greater than the output current required.

ECO Mode Operation

By default the DC-DC converter will be in Auto (ECO/PWM) Mode. By doing so the part switches from ECO (EConomy) state to PWM (Pulse Width Modulation) state based on output load current. At light loads (less than 75mA approx) the converter enters ECO mode. In this mode the part operates with low I_q . During ECO operation the converter positions the output voltage slightly higher (+30mV typ.) than the nominal output voltage in PWM operation. Because the reference is set higher, the output voltage increases to reach the target voltage when the part goes from sleep state to switching state. Once this voltage is reached the converter enters sleep mode, thereby reducing switching losses and improving light load efficiency. The output voltage ripple is slightly higher in ECO mode (30mV p-p typ.).

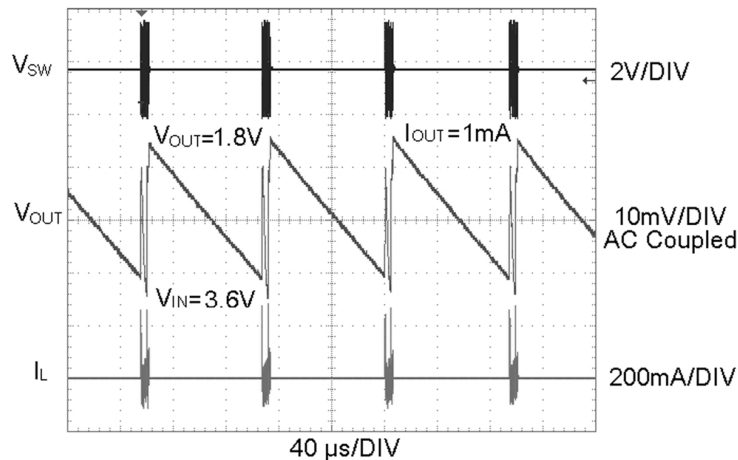


Figure 14. Typical ECO Operation

Note that ground noise may impact quiescent current in ECO mode and care at board layout is important to minimize this risk. See section on layout guidelines.

Startup

The LP8725 bucks have a 'soft-start' feature to limit the in-rush current. This prevents large current spikes and voltage overshoot and also limits the cases in which the inductor may saturate. At or close to 0V the inrush current to the capacitor (and load) is limited to its short circuit protection limit of typically 500 mA. Above a threshold of around 150 mV, the current limit is increased to the buck's peak current limit set by the control registers. (For a 600 mA max load this is set to approx. 1050 mA.)

While in short-circuit protection, the output switches off, but will continue to attempt to restart. If the total capacitance on the buck output is large or if the inductor value drops too low, the threshold might never be reached, so the buck may not start. See [Inductor Selection](#) and [Output Capacitor Selection](#) sections.

Stability

The stability of the buck is optimized for the 4.7 μF capacitors recommended in the datasheet. Either too small or too large a capacitance can cause an oscillation at the output and/or excessive ringing during load transients. It is advisable not to exceed a total of 15 μF capacitance at the output. See [Table 14](#) for recommended output capacitors.

See also the recommended inductors table ([Table 13](#)) as stability may be compromised by the use of inductors whose actual value may change significantly from its nominal value due to the operating conditions. This may be the case for the smaller case size chip inductors.

APPLICATION INFORMATION

Inductor Selection

DC bias current characteristics of inductors must be considered. Different manufacturers follow different saturation current rating specifications, so attention must be given to details. DC bias curves should be requested from them as part of the inductor selection process.

Minimum value of inductance to guarantee good performance is 0.5 μH at 1.5A (I^{LIM} typ.) bias current over the ambient temp range. The inductor's DC resistance should be less than 0.1Ω for good efficiency at high current condition. The inductor AC loss (resistance) also affects conversion efficiency. Higher Q factor at switching frequency usually gives better efficiency at light load to medium load instead. [Table 13](#) lists suggested inductors and suppliers.

Input Capacitor Selection

A ceramic input capacitor of $4.7\mu\text{F}$, 6.3V/10V is sufficient for most applications. Place the input capacitor as close as possible to the V_{IN} pin and GND pin of the device. A larger value or higher voltage rating may be used to improve input voltage filtering. Use X7R, X5R or B types, do not use Y5V or F.

Minimum input capacitance to guarantee good performance is 4.7 μF at maximum input voltage DC bias including tolerances and over ambient temp range. The input filter capacitor supplies current to the PFET (high-side) switch in the first half of each cycle and reduces voltage ripple imposed on the input power source. A ceramic capacitor's low ESR provides the best noise filtering of the input voltage spikes due to this rapidly changing current. Select an input filter capacitor with sufficient ripple current rating. The input current ripple can be calculated as:

$$I_{\text{RMS}} = I_{\text{OUTMAX}} \times \sqrt{\frac{V_{\text{OUT}}}{V_{\text{IN}}} \times 1 - \frac{V_{\text{OUT}}}{V_{\text{IN}}} + \frac{r^2}{12}} \quad (1)$$

$$\text{where } r = \frac{(V_{\text{in}} - V_{\text{out}}) \times V_{\text{out}}}{L \times f \times I_{\text{outmax}} \times V_{\text{in}}} \quad (2)$$

Output Capacitor Selection

Use a $4.7\mu\text{F}$, 6.3V ceramic capacitor, X7R, X5R or B types, do not use Y5V or F. DC bias voltage characteristics of ceramic capacitors must be considered. DC bias characteristics vary from manufacturer to manufacturer and DC bias curves should be requested from them as part of the capacitor selection process. The output filter capacitor smooths out current flow from the inductor to the load, helps maintain a steady output voltage during transient load changes and reduces output voltage ripple. These capacitors must be selected with sufficient capacitance and sufficiently low ESR to perform these functions.

Minimum output capacitance to guarantee good performance is 2.2 μF at the output voltage DC bias including tolerances and over ambient temp range. The output voltage ripple is caused by the charging and discharging of the output capacitor and also due to its ESR and can be calculated as:

$$\text{Voltage peak to peak ripple due to capacitance} = V_{\text{PP-C}} = \frac{I_{\text{RIPPLE}}}{4 \times f \times C}$$

$$\text{Voltage peak-to-peak ripple due to ESR} = V_{\text{PP-ESR}} = (2 \times I_{\text{RIPPLE}}) \times R_{\text{ESR}}$$

Because these two components are out of phase the rms value can be used to get an approximate value of peak-to-peak ripple.

$$\text{Voltage peak-to-peak ripple, root mean squared} = V_{\text{PP-RMS}} = \sqrt{V_{\text{PP-C}}^2 + V_{\text{PP-ESR}}^2}$$

Note that the output ripple is dependent on the current ripple and the equivalent series resistance of the output capacitor (ESR). The RESR is frequency dependent (as well as temperature dependent); make sure the value used for calculations is at the switching frequency of the part.

[Table 14](#) lists suggested capacitors and suppliers.

Table 13. Suggested Inductors and Suppliers

Model	Vendor	Dimensions LxWxH (mm)	DCR (mΩ)
LQM2HPN 1R0MG0	Murata	2.5 x 2.0 x 1.0 (Max)	55
MIPSZ2520D1R0	FDK	2.5 x 2.0 x 1.0 (Max)	90
MIPSZ2012D1R0	FDK	2.0 x 1.25 x 1.0 (Max)	90
LPS3010-102NLC	Coilcraft	3.3 x 3.3 x 1.0 (Max)	85

Table 14. Suggested Capacitors and Suppliers

Model	Type	Vendor	Voltage Rating	Case Size Inch (mm)
4.7 μF for C_{IN} and C_{OUT}				
C1608X5R0J475K	Ceramic	TDK	6.3	0603 (1608)
C1608X5R1A475K	Ceramic	TDK	10	0603 (1608)

Dynamic Voltage Scaling

Buck 1 and Buck 2 can be switched between two output values stored in registers 0x08 and 0x09 for Buck1 and 0x0A and 0x0B for Buck2.

For Buck 2 output this control is achieved by changing the DVS2_V bit in the GENERAL register 0x00 (bit 3).

DVS2_V	OUTPUT	
Reg0x00 Bit3		
0	BUCK2_V2	Reg 0x0B[4-0]
1	BUCK2_V1	Reg 0x0A[4-0]

For Buck 1 this control can be either via the external DVS pin or via the DVS1_V bit in the GENERAL register 0x00 (bit 2). The control configurations are shown in the following table.

DVS1	DVS pin	OUTPUT	
Reg0x00 Bit2			
0	0	BUCK1_V2	Reg 0x09[4-0]
0	1	BUCK1_V1	Reg 0x08[4-0]
1	0	BUCK1_V2	Reg 0x09[4-0]
1	1	BUCK1_V1	Reg 0x08[4-0]

LDO Information

There are all together 7 LDOs in LP8725 grouped as

- DIGITAL;
- ANALOG; and
- LOW INPUT LOW OUTPUT (LILO)

All LDOs can be programmed through serial interface for different output voltage values, which are summarized in the output voltage selection tables.

At the PMU power on, LDOs startup according to the selected startup sequence and the default voltages. See STARTUP and SHUTDOWN Sequences for details.

For stability all LDOs need to have external capacitors C_{OUT} connected to the output with recommended value of 1μF. It is important to select the type of capacitor whose capacitance will in no case (voltage, temperature, etc) be outside of limits specified in the LDO electrical characteristics.

Analog-Type LDOs

The analog LDOs are optimized for supplying analog loads having ULTRA LOW NOISE (10 μ V_{RMS} for $I_{OUT} > 5$ mA) and excellent PSRR (70 dB at 10 kHz) performance. They can be programmed through serial interface for different output voltage values.

For fast discharging of output capacitors in shutdown, the LDOs may be connected to a 300 Ω pull down resistor to output.

In sleep mode quiescent current is lowered down to 30 μ A for energy saving. In this mode these LDOs should not loaded more than 3-5 mA of output current.

Digital-Type LDOs

The Digital LDOs are optimized for dynamic performance for fast changing digital loads whilst consuming very little quiescent current ~ 20 μ A . They can be programmed through serial interface for different output voltage values.

For fast discharging of output capacitors in shutdown, the LDOs may be connected to a 300 Ω pull down resistor to output.

In sleep mode quiescent current is lowered down to 10 μ A for energy saving. In this mode these LDOs should not loaded more than 3-5 mA of output current.

LILO-Type LDOs

The LILO-type LDO is optimized for low output voltage and for good dynamic performance to supply different fast changing (digital) loads. These LDOs can be operated as digital LDOs also albeit with lower PSRR and Noise performance.

An innovative design of the all the LDOs reduces sensitivity to the placement of the output capacitor. The output capacitor may not be placed as close as possible to the output pin, like on conventional LDOs. The general purpose LDOs do not need output capacitor close to the PMU. If a (1 μ F or more) capacitor is attached to a circuit load, customer may skip the output capacitor at the PMU.

I²C-Compatible Serial Bus Interface

Interface Bus Overview

The I²C-compatible synchronous serial interface provides access to the programmable functions and registers on the device.

This protocol uses a two-wire interface for bi-directional communications between the ICs connected to the bus. The two interface lines are the Serial Data Line (SDA), and the Serial Clock Line (SCL). These lines should be connected to a positive supply, via a pull-up resistor of 1.5 K Ω and remain HIGH even when the bus is idle.

Every device on the bus is assigned a unique address and acts as either a Master or a Slave depending on whether it generates or receives the serial clock (SCL).

Data Transactions

One data bit is transferred during each clock pulse. Data is sampled during the high state of the serial clock (SCL). Consequently, throughout the clock's high period, the data should remain stable. Any changes on the SDA line during the high state of the SCL and in the middle of a transaction, aborts the current transaction. New data should be sent during the low SCL state. This protocol permits a single data line to transfer both command/control information and data using the synchronous serial clock.

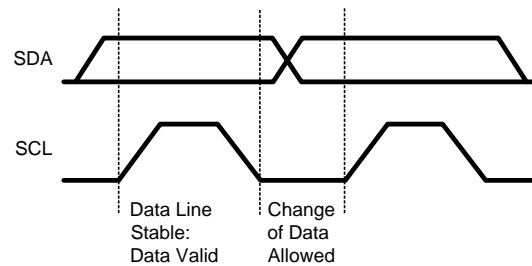


Figure 15. Bit Transfer

Each data transaction is composed of a Start Condition, a number of byte transfers (set by the software) and a Stop Condition to terminate the transaction. Every byte written to the SDA bus must be 8 bits long and is transferred with the most significant bit first. After each byte, an Acknowledge signal must follow. The following sections provide further details of this process.

Start and Stop

The Master device on the bus always generates the Start and Stop Conditions (control codes). After a Start Condition is generated, the bus is considered busy and it retains this status until a certain time after a Stop Condition is generated. A high-to-low transition of the data line (SDA) while the clock (SCL) is high indicates a Start Condition. A low-to-high transition of the SDA line while the SCL is high indicates a Stop Condition.

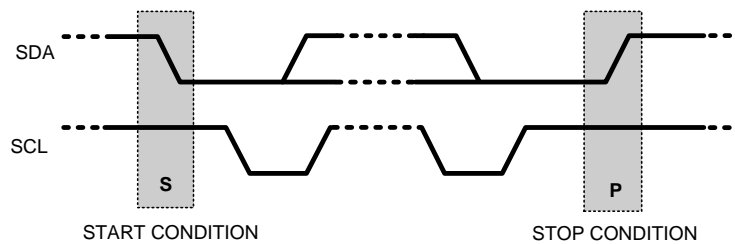


Figure 16. Start and Stop Conditions

In addition to the first Start Condition, a repeated Start Condition can be generated in the middle of a transaction. This allows another device to be accessed, or a register read cycle.

Acknowledge Cycle

The Acknowledge Cycle consists of two signals: the acknowledge clock pulse the master sends with each byte transferred, and the acknowledge signal sent by the receiving device. The master generates the acknowledge clock pulse on the ninth clock pulse of the byte transfer. The transmitter releases the SDA line (permits it to go high) to allow the receiver to send the acknowledge signal. The receiver must pull down the SDA line during the high period of the clock pulse, thus signaling the correct reception of the last data byte and its readiness to receive the next byte.

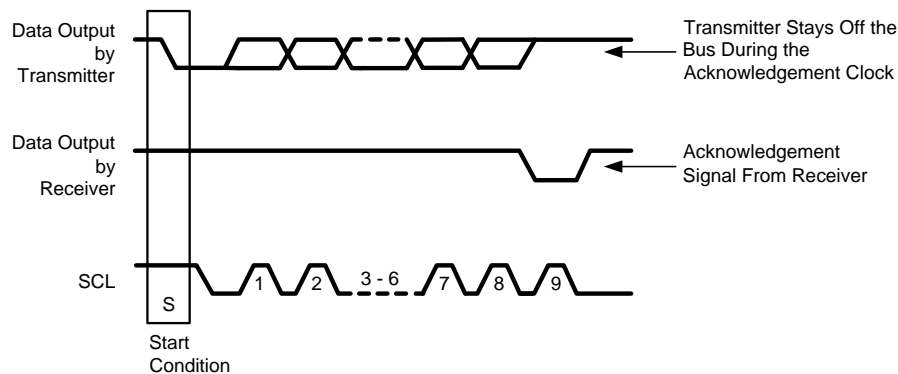


Figure 17. Bus Acknowledge Cycle

”Acknowledge after Every Byte” Rule

The master generates an acknowledge clock pulse after each byte transfer. The receiver sends an acknowledge signal after every byte received.

There is one exception to the “acknowledge after every byte” rule.

When the master is the receiver, it must indicate to the transmitter an end of data by not-acknowledging (“negative acknowledge”) the last byte clocked out of the slave. This “negative acknowledge” still includes the acknowledge clock pulse (generated by the master), but the SDA line is not pulled down.

Addressing Transfer Formats

Each device on the bus has a unique slave address. The LP8725 operates as a slave device. Slave address is selectable by CONFIG and DEFSEL pins.

For the actual slave addresses, see [Table 1](#).

Before any data is transmitted, the master transmits the address of the slave being addressed. The slave device should send an acknowledge signal on the SDA line, once it recognizes its address.

The slave address is the first seven bits after a Start Condition. The direction of the data transfer (R/W) depends on the bit sent after the slave address the eighth bit.

When the slave address is sent, each device in the system compares this slave address with its own. If there is a match, the device considers itself addressed and sends an acknowledge signal. Depending upon the state of the R/W bit (1:read, 0:write), the device acts as a transmitter or a receiver.

Control Register Write Cycle

- Master device generates start condition.
- Master device sends slave address (7 bits) and the data direction bit (r/w = '0').
- Slave device sends acknowledge signal if the slave address is correct.
- Master sends control register address (8 bits).
- Slave sends acknowledge signal.
- Master sends data byte to be written to the addressed register.
- Slave sends acknowledge signal.
- If master will send further data bytes the control register address will be incremented by one after acknowledge signal.
- Write cycle ends when the master creates stop condition.

Control Register Read Cycle

- Master device generates a start condition.
- Master device sends slave address (7 bits) and the data direction bit (r/w = '0').
- Slave device sends acknowledge signal if the slave address is correct.

- Master sends control register address (8 bits).
- Slave sends acknowledge signal.
- Master device generates repeated start condition.
- Master sends the slave address (7 bits) and the data direction bit (r/w = "1").
- Slave sends acknowledge signal if the slave address is correct.
- Slave sends data byte from addressed register.
- If the master device sends acknowledge signal, the control register address will be incremented by one. Slave device sends data byte from addressed register.
- Read cycle ends when the master does not generate acknowledge signal after data byte and generates stop condition.

	Address Mode
Data Read	<Start Condition> <Slave Address><r/w = '0'>[Ack] <Register Addr.>[Ack] <Repeated Start Condition> <Slave Address><r/w = '1'>[Ack] [Register Data]<Ack or NAck> ... additional reads from subsequent register address possible <Stop Condition>
Data Write	<Start Condition> <Slave Address><r/w = '0'>[Ack] <Register Addr.>[Ack] <Register Data>[Ack] ... additional writes to subsequent register address possible <Stop Condition>

< > Data from master [] Data from slave

Register Read and Write Detail

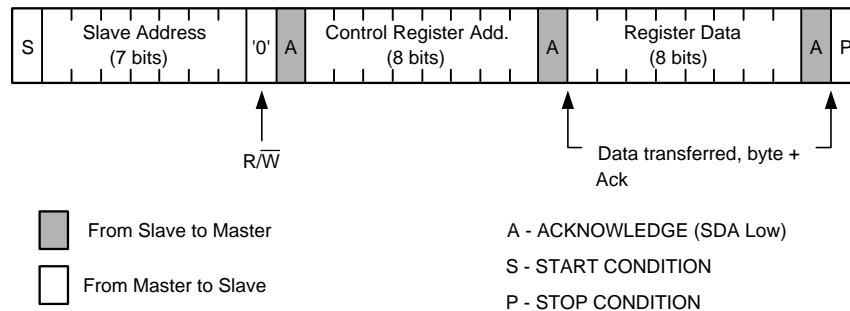


Figure 18. Register Write Format

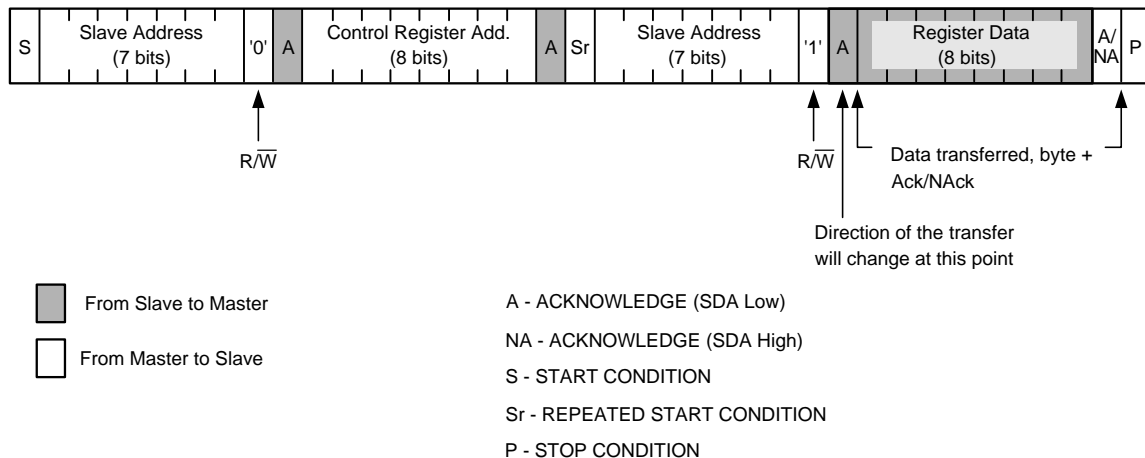


Figure 19. Register Read Format

Layout Guidelines

As for all DC-DC buck regulators board layout is very important to ensure best performance.

The 4.7 μF input capacitors should be placed first, as near to VINB1/2 pin and GNDB1/2 as possible. VINB1/2 are the voltage rails for the high-side power FETs. GNDB1/2 are the return paths for the low-side power FETs. The input capacitors should have their associated pads very near the pins that they will decouple. These capacitors are important in sourcing charge during switching events. In this device we have the two buck inputs side by side but we recommend that separate traces are taken to each device pin to ensure this proper decoupling. This can be seen in the example layout shown in the layout scheme below.

The 4.7 μF output capacitors should be the next components to be placed in conjunction with the inductor. The switch node should be kept as small as possible but otherwise the inductor placement is least sensitive to layout variation. Best performance of the LP8725 will be realized by maintaining tight physical coupling of the grounds of the input capacitor, output capacitor and GND pin for each switcher. The inductor should be placed in a way that best allows the switching node, output node, and track to the load circuit to be routed easily.

The grounding is very important and any additional resistance/inductance should be minimized. A ground polygon and/or plane should be used to tie all capacitor grounds together and directly to the buck GNDs. See the layout scheme below as an example.

Finally, the feedback nets should be routed, where possible route this away from any switching nodes and tie into the output node of the regulator. The FB lines should closely match the GND routing to reduce the inductive loop of this pair. The FB and GND lines make up a high-side and low-side sense connection to maintain the accuracy of the switcher outputs. If the FB line should cross the switching trace make this as close to perpendicular as possible.

Low impedance power connections should be maintained for all of these connections. Care should also be given to the ground routing for input lines and output lines to minimize inductive loops, normally this should be taken care of by suitable ground planes.

As this is a dual buck device there are a number of aspects to be aware of. The switchers are almost a complete mirror image of one another on the part which leads to the possibility of symmetrical placement and layout about the part. Symmetrical layout will give best matching between the two buck devices. However we recommend that the inputs are kept separate into the device. There are some compromises that have to be considered. In the case of our example we have used vias to route the VINB12 and VINB2 to allow the close placement of the input capacitors. The switch node must also be routed via layer2 on the board. Here we have placed a number of vias to reduce any additional impedance.

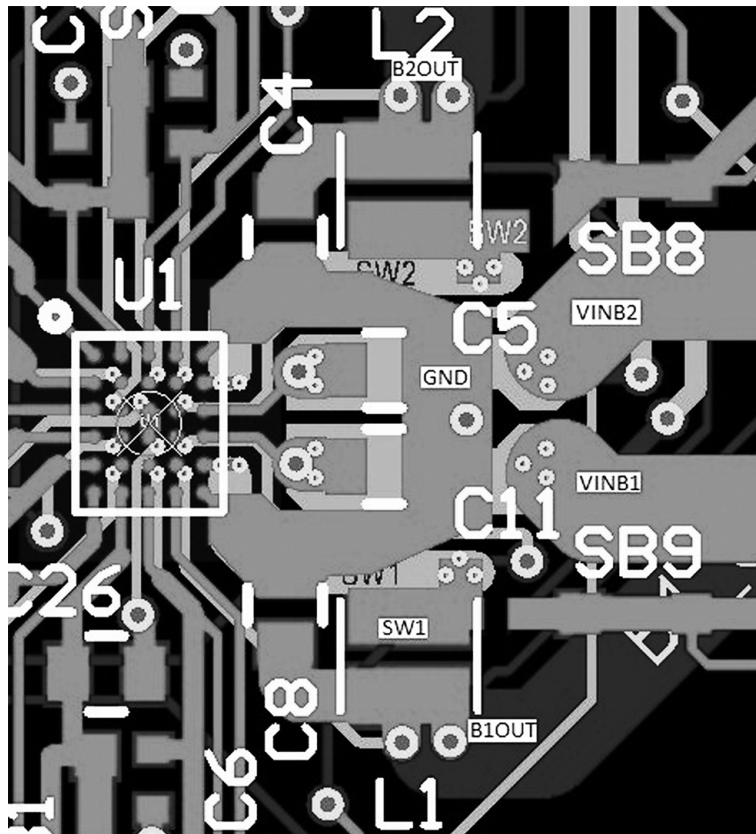


Figure 20. Layout Scheme used on Eval Board

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LP8725TLE-A/NOPB	ACTIVE	DSBGA	YZR	30	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	V023	Samples
LP8725TLE-B/NOPB	ACTIVE	DSBGA	YZR	30	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	V028	Samples
LP8725TLE-C/NOPB	ACTIVE	DSBGA	YZR	30	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	V040	Samples
LP8725TLE-D/NOPB	ACTIVE	DSBGA	YZR	30	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM		V031	Samples
LP8725TLE/NOPB	ACTIVE	DSBGA	YZR	30	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	8725	Samples
LP8725TLX-A/NOPB	ACTIVE	DSBGA	YZR	30	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	V023	Samples
LP8725TLX-B/NOPB	ACTIVE	DSBGA	YZR	30	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	V028	Samples
LP8725TLX-C/NOPB	ACTIVE	DSBGA	YZR	30	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	V040	Samples
LP8725TLX-D/NOPB	ACTIVE	DSBGA	YZR	30	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM		V031	Samples
LP8725TLX/NOPB	ACTIVE	DSBGA	YZR	30	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	8725	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

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TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

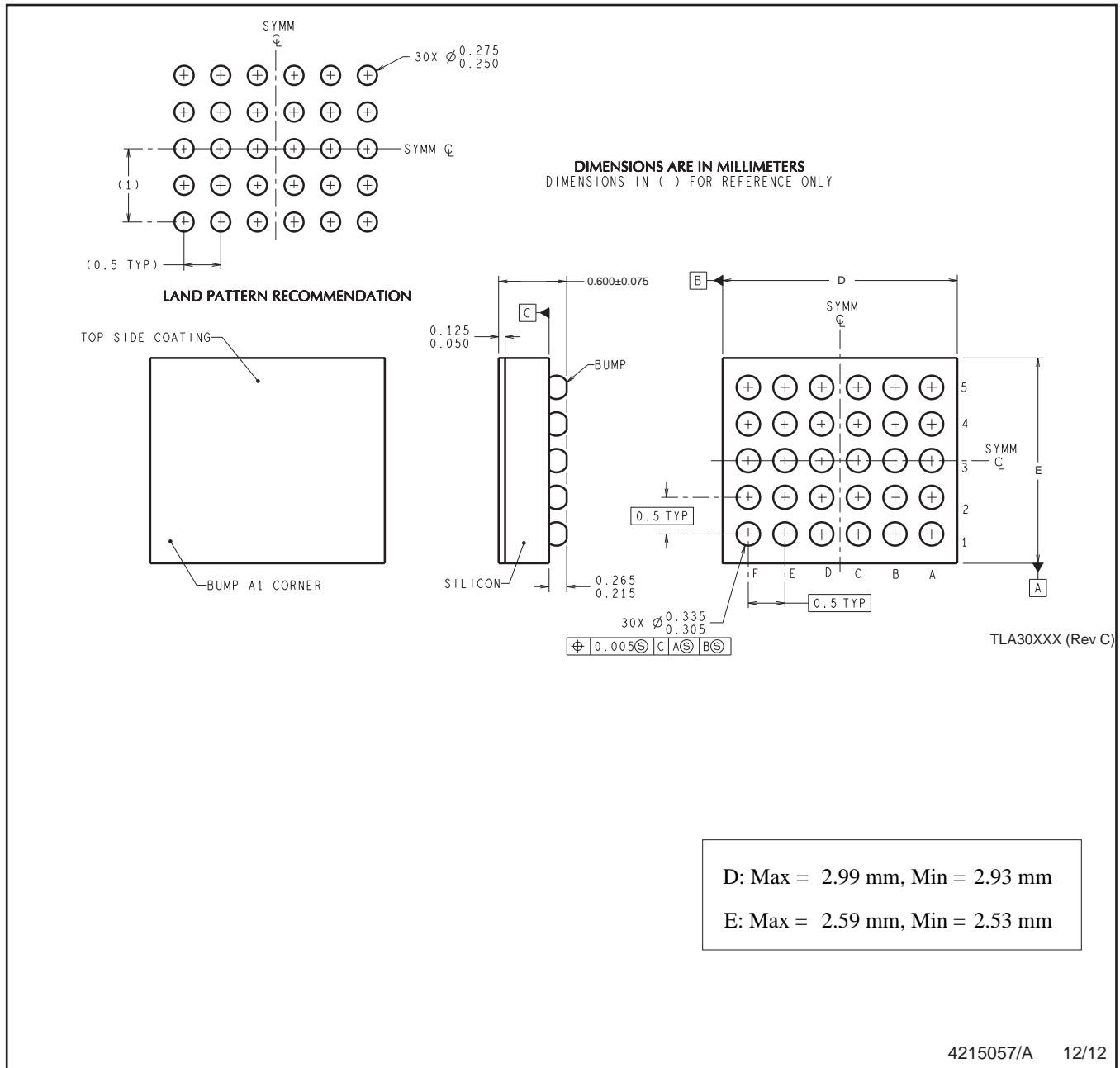
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LP8725TLE-A/NOPB	DSBGA	YZR	30	250	178.0	8.4	2.74	3.15	0.76	4.0	8.0	Q1
LP8725TLE-B/NOPB	DSBGA	YZR	30	250	178.0	8.4	2.74	3.15	0.76	4.0	8.0	Q1
LP8725TLE-C/NOPB	DSBGA	YZR	30	250	178.0	8.4	2.74	3.15	0.76	4.0	8.0	Q1
LP8725TLE-D/NOPB	DSBGA	YZR	30	250	178.0	8.4	2.74	3.15	0.76	4.0	8.0	Q1
LP8725TLE/NOPB	DSBGA	YZR	30	250	178.0	8.4	2.74	3.15	0.76	4.0	8.0	Q1
LP8725TLX-A/NOPB	DSBGA	YZR	30	3000	178.0	8.4	2.74	3.15	0.76	4.0	8.0	Q1
LP8725TLX-B/NOPB	DSBGA	YZR	30	3000	178.0	8.4	2.74	3.15	0.76	4.0	8.0	Q1
LP8725TLX-C/NOPB	DSBGA	YZR	30	3000	178.0	8.4	2.74	3.15	0.76	4.0	8.0	Q1
LP8725TLX-D/NOPB	DSBGA	YZR	30	3000	178.0	8.4	2.74	3.15	0.76	4.0	8.0	Q1
LP8725TLX/NOPB	DSBGA	YZR	30	3000	178.0	8.4	2.74	3.15	0.76	4.0	8.0	Q1

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LP8725TLE-A/NOPB	DSBGA	YZR	30	250	210.0	185.0	35.0
LP8725TLE-B/NOPB	DSBGA	YZR	30	250	210.0	185.0	35.0
LP8725TLE-C/NOPB	DSBGA	YZR	30	250	210.0	185.0	35.0
LP8725TLE-D/NOPB	DSBGA	YZR	30	250	210.0	185.0	35.0
LP8725TLE/NOPB	DSBGA	YZR	30	250	210.0	185.0	35.0
LP8725TLX-A/NOPB	DSBGA	YZR	30	3000	210.0	185.0	35.0
LP8725TLX-B/NOPB	DSBGA	YZR	30	3000	210.0	185.0	35.0
LP8725TLX-C/NOPB	DSBGA	YZR	30	3000	210.0	185.0	35.0
LP8725TLX-D/NOPB	DSBGA	YZR	30	3000	210.0	185.0	35.0
LP8725TLX/NOPB	DSBGA	YZR	30	3000	210.0	185.0	35.0

YZR0030



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
B. This drawing is subject to change without notice.

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